

# TI *Live!* INDIA AUTOMOTIVE SEMINAR

## ORLANDO MURRAY

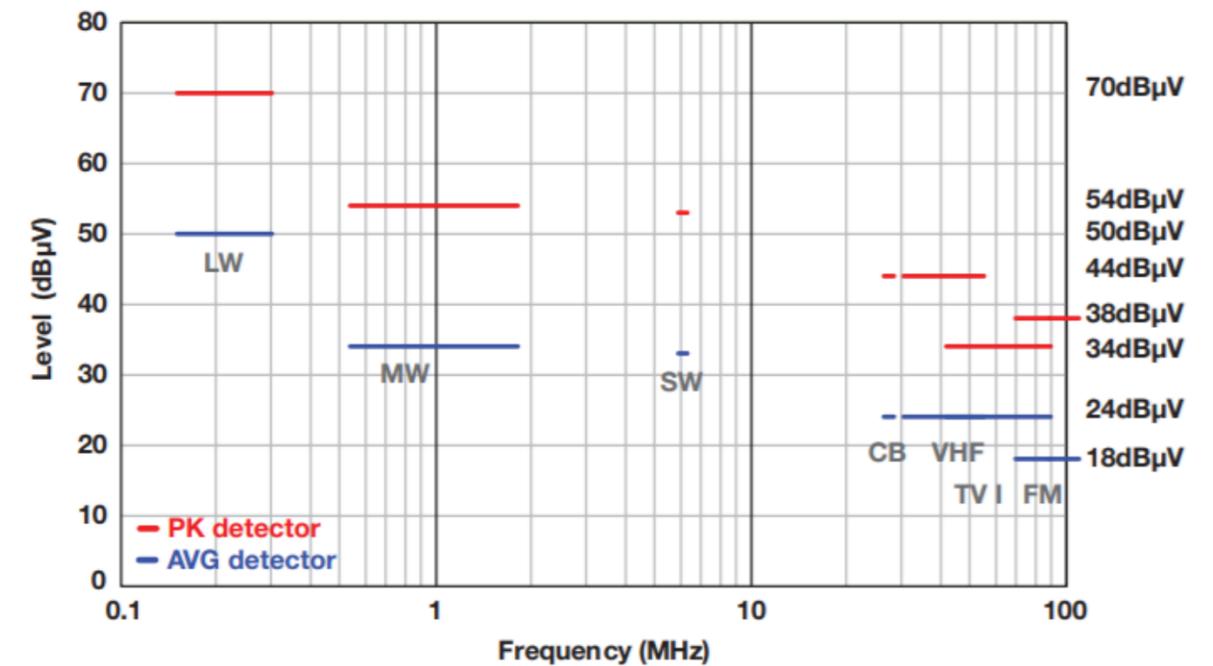
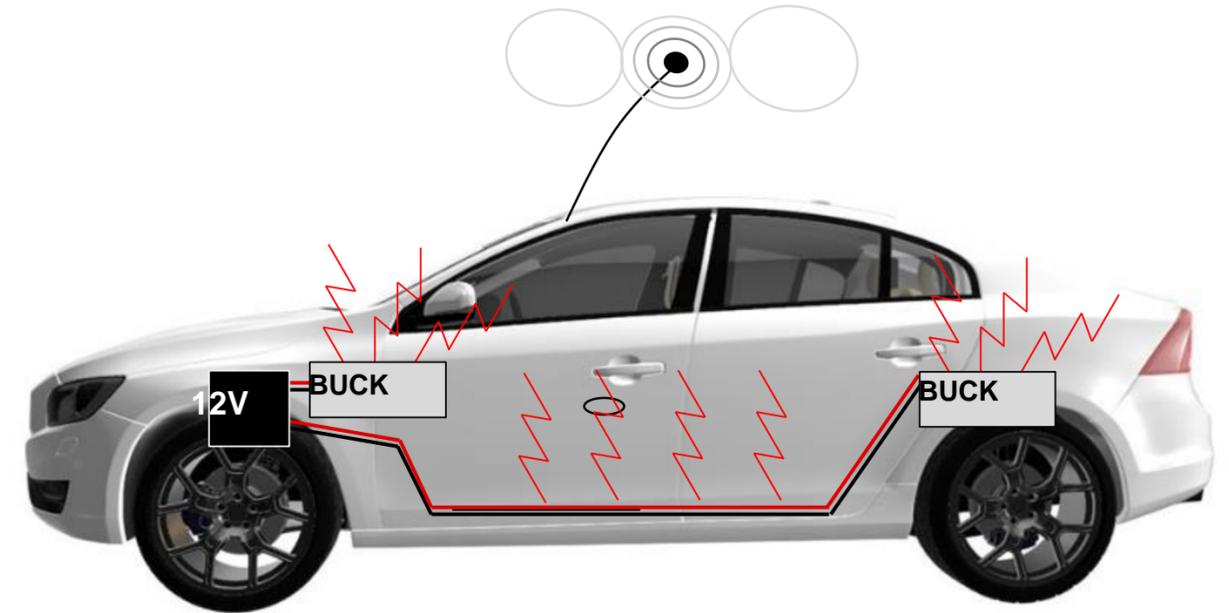
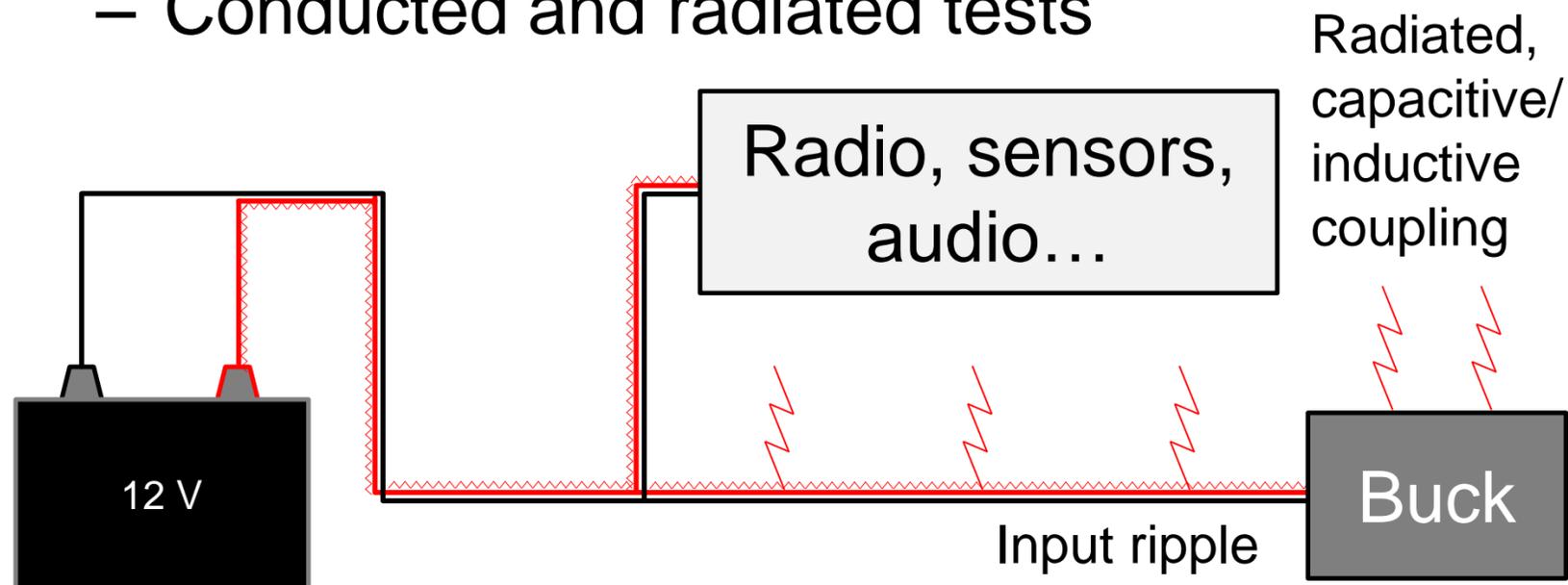
USING AN ACTIVE EMI FILTER IN POWER  
CONVERTERS TO REDUCE EMI FILTER SIZE  
AND COST

# Outline

- Background and context:
  - What is electromagnetic interference (EMI)
  - How to mitigate EMI
  - EMI filters and limitations
- Active EMI filter
  - Active EMI filter (AEF)
  - AEF compensation
  - AEF damping
- Results

# Background: What is EMI and why do we care?

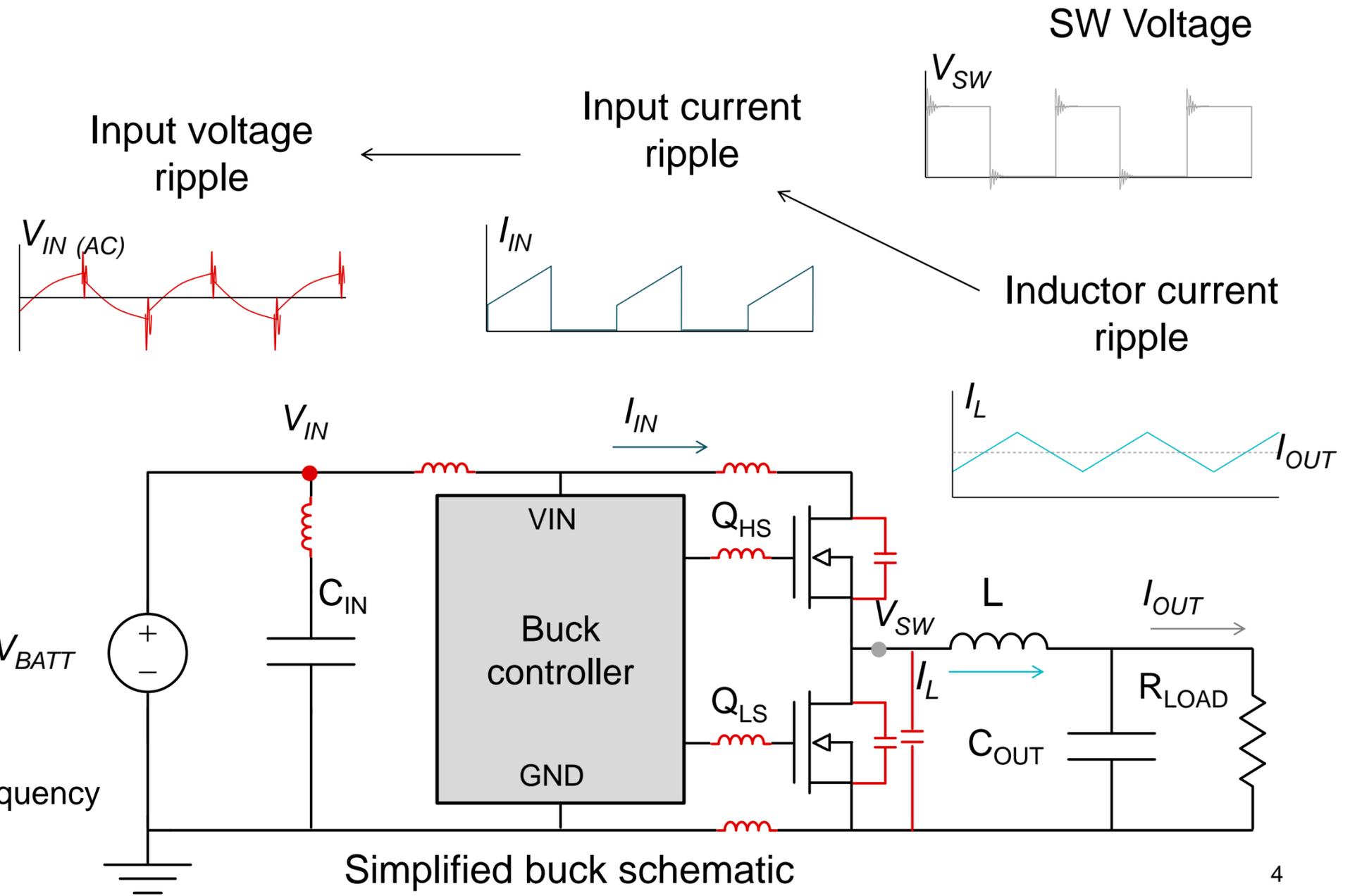
- EMI: Unwanted noise and signals that cause capacitive coupling, inductive coupling, or radiation onto a conductor
- Can interfere with other systems
- Standards limit how much we can emit
  - CISPR 25, CISPR 11... standards
  - Conducted and radiated tests



Conducted EMI limits – CISPR 25 Class 5

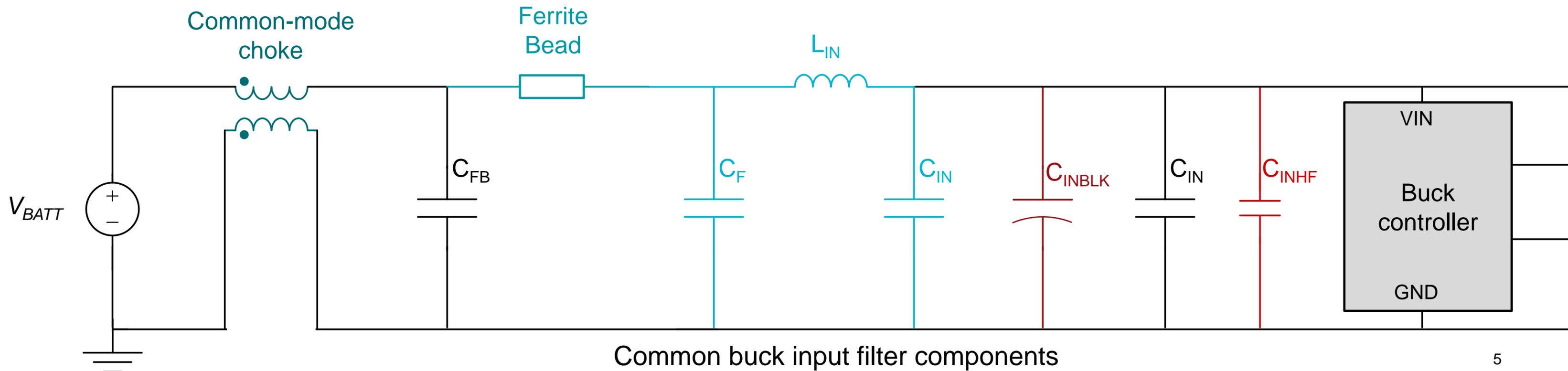
# Context: What causes EMI in a buck regulator?

- Switching causes ripple/noise at  $f_{SW}$  and harmonics
- Parasitics cause high-frequency SW ring and spikes
- Jitter, spread spectrum can add low-frequency noise



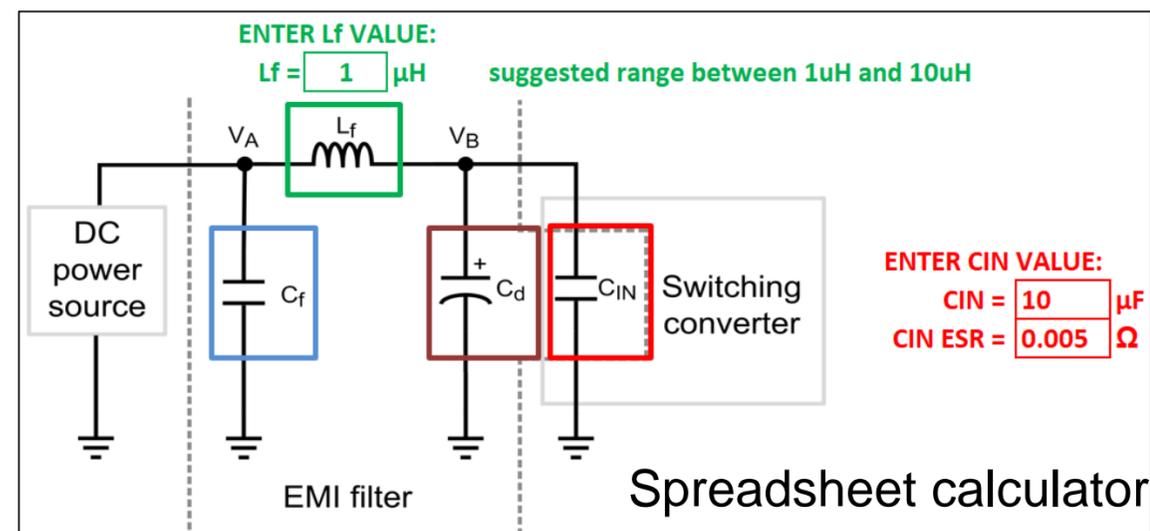
# EMI filtering: Common passive components

- **HF ceramic input capacitor** - Reduces SW ringing, improves  $>10$  MHz
- **Bulk capacitor** - ESR damps resonance with filter components at  $<1$  MHz
- **CLC/LCL  $\pi$ /T-filter** - Filters up to 10 -100 MHz
- **Ferrite bead** - Filters  $>2$  MHz, spec'd at 100 MHz
- **Common-mode choke** - Filters common-mode noise up to  $\sim 100$ -300 MHz



# EMI filtering: Designing a CLC $\pi$ filter

- Three methods:
  - A. Check the evaluation board or a reference design
    - Check data sheet and user's guide for EMI results and filter
    - Use something similar or adjust to your specs
  - B. Calculate/measure
    - Calculate attenuation using equation (1) or measure necessary attenuation
    - Use [AN-2162](#) application note and [spreadsheet](#) to calculate component values
  - C. Test in lab and adjust until the filter is optimized



$$|Att|_{dB} = 20 \log \left( \frac{I_{peak} \sin(\pi D)}{\pi^2 f_{SW} C_{IN}} \right) - V_{MAX} \quad (1)$$

Where:

$f_{SW}$  = Switching frequency

$D$  = Duty cycle

$V_{MAX}$  = Max allowed dB $\mu$ V for the particular EMI spec

# EMI filtering: Designing a CLC $\pi$ filter

- After measuring or using (1) to calculate required attenuation in dB
- Use (2) to design EMI filter cutoff frequency
- Use (3) to select  $C_F$  and  $L_{IN}$  components
  - Typically select  $L_{IN}$  0.1–10  $\mu\text{H}$  with input current rating
  - Typically parallel multiple  $C_F$  to get required value
- Test and adjust as needed

$$|Att|_{dB} = 20 \log \left( \frac{I_{peak} \sin(\pi D)}{\pi^2 f_{sw} C_{IN}} \right) - V_{MAX} \quad (1)$$

Where:

$f_{sw}$  = Switching frequency

$D$  = Duty cycle

$V_{MAX}$  = Max allowed  $\text{dB}\mu\text{V}$  for the particular EMI spec

$$f_c = \frac{f_{sw}}{10^{|Att|/40}} \quad (2)$$

Where:

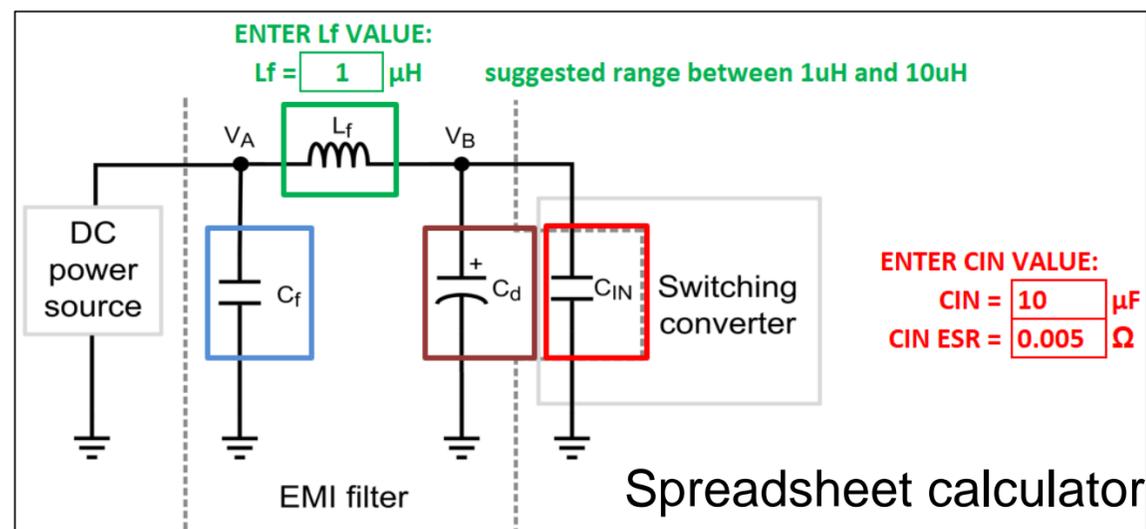
$f_c$  = EMI filter cutoff frequency

$$L_{IN} C_F = \frac{1}{(2\pi f_c)^2} \quad (3)$$

Where:

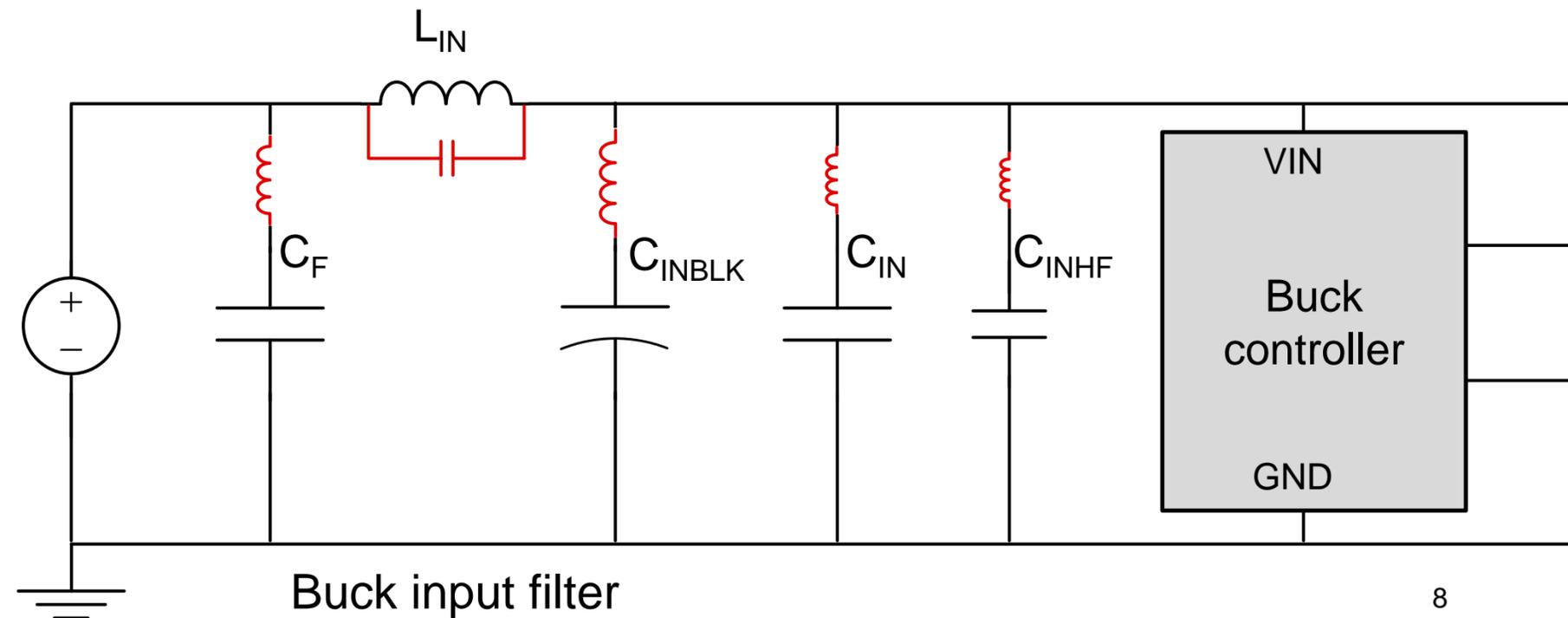
$L_{IN}$  = EMI filter inductor

$C_F$  = EMI filter inductor



# EMI filtering: Passive filter component limitations

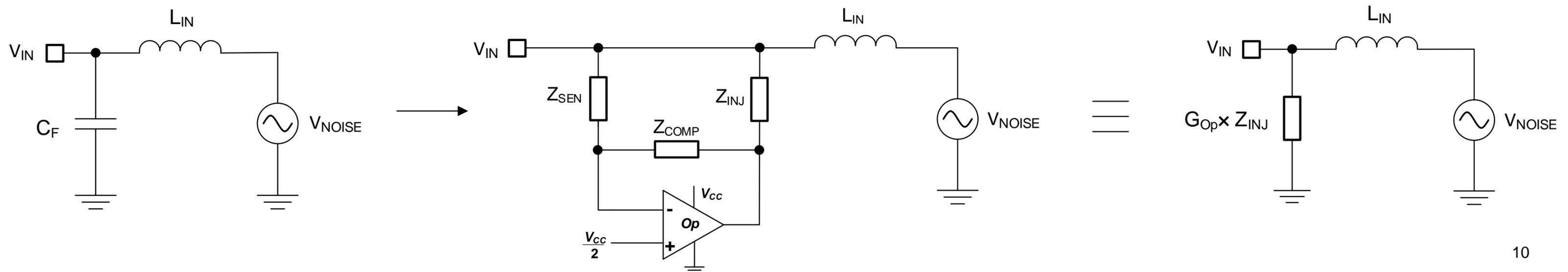
- Concerns:
  - Cost – Filter cost can add up. Larger filter for more attenuation means more money!
  - Size – Filter can take large board area depending on necessary components
- Considerations:
  - Capacitor voltage rating must  $> V_{IN\_MAX}$
  - Inductor current rating must  $> I_{IN\_MAX}$  (at  $V_{IN\_MIN}$ )
- Filter components' **parasitics** limit filtered frequencies to less than self-resonant frequency (SRF)
- Larger package = more **parasitics**
  - 1210 capacitor  $\sim 1\text{--}2$  nH
  - 0402 capacitor  $\sim < 1$  nH



# Active EMI filter

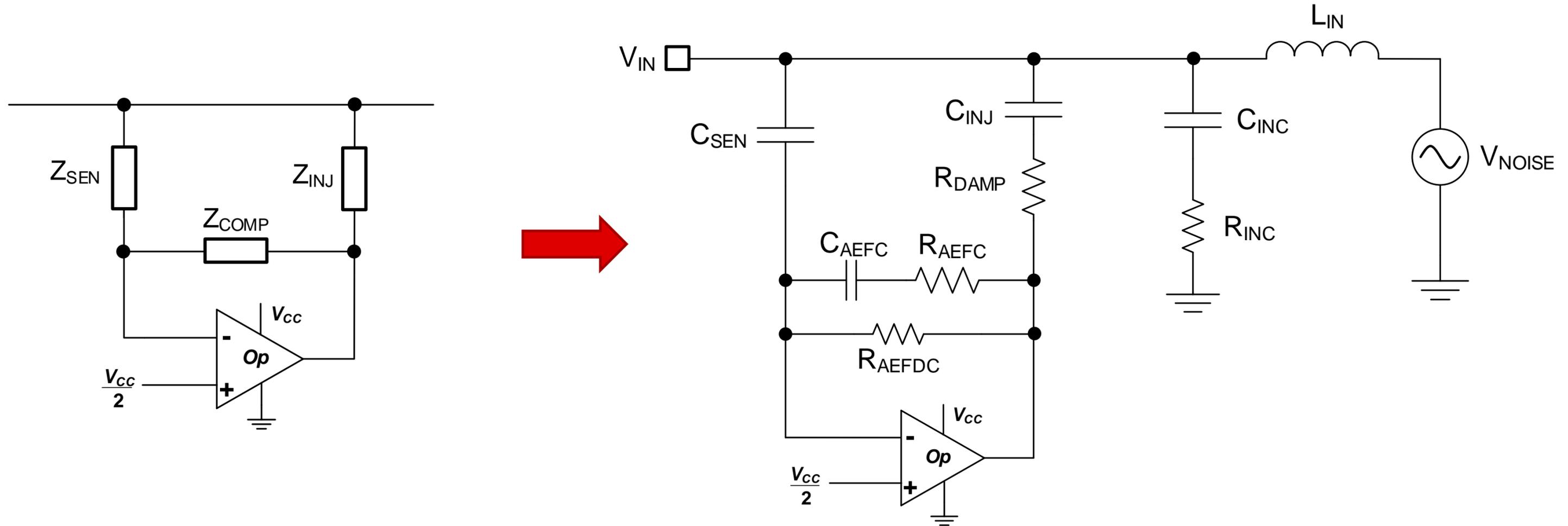
# Active EMI fundamentals

- View Active EMI filter (AEF) as an “active capacitor” compared to passive  $C_F$ .
- AEF uses an operational amplifier to sense AC-perturbations on the input rail and inject an  $180^\circ$  out-of-phase signal to cancel the noise.
- Replace passive EMI filter  $C_F$  with active EMI network; Op-amp requires feedback and compensation components but these are much smaller in capacitance, footprint, and cost.
- Op-amp can be integrated in DC/DC controller IC, such as LM25149-Q1.



# EMI filtering: Active EMI filter

- Active EMI filter uses an op-amp to replace passive  $C_F$  with “active capacitor”



# EMI filtering: Active EMI filter

- Active EMI filter uses an op-amp to replace passive  $C_F$  with “active capacitor”
- Op-amp gain term (5)

$$G_{Op} \approx C_{SEN} / C_{AEFC} \quad (5)$$

Where:

$C_{SEN}$  = AEF sensing capacitor

$C_{AEFC}$  = AEF compensation capacitor

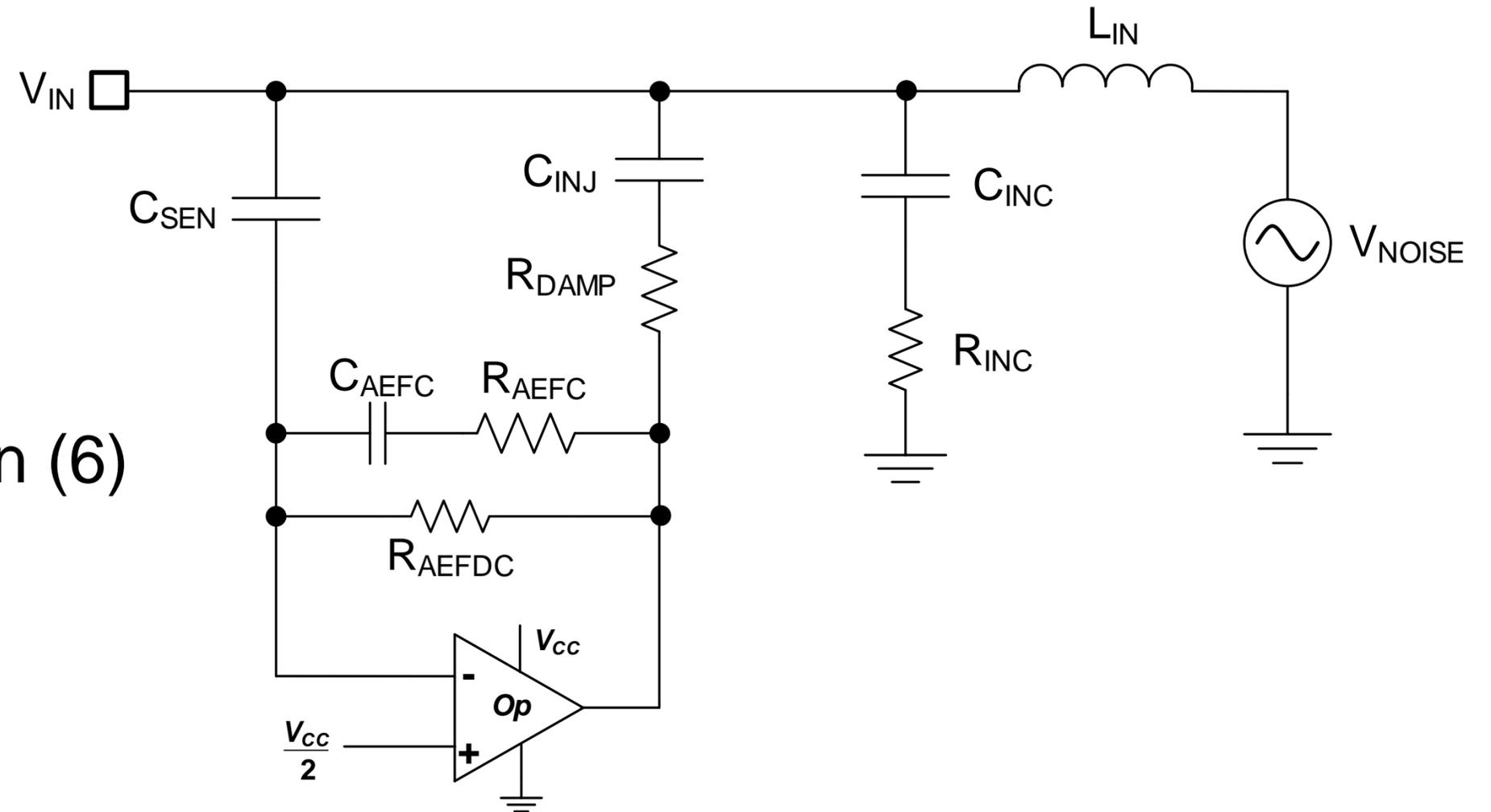
- Active filter  $L_{IN}$  and  $C_{INJ}$  selection (6)

$$L_{IN} C_{INJ} = \frac{1}{G_{Op} (2\pi f_c)^2} \quad (6)$$

Where:

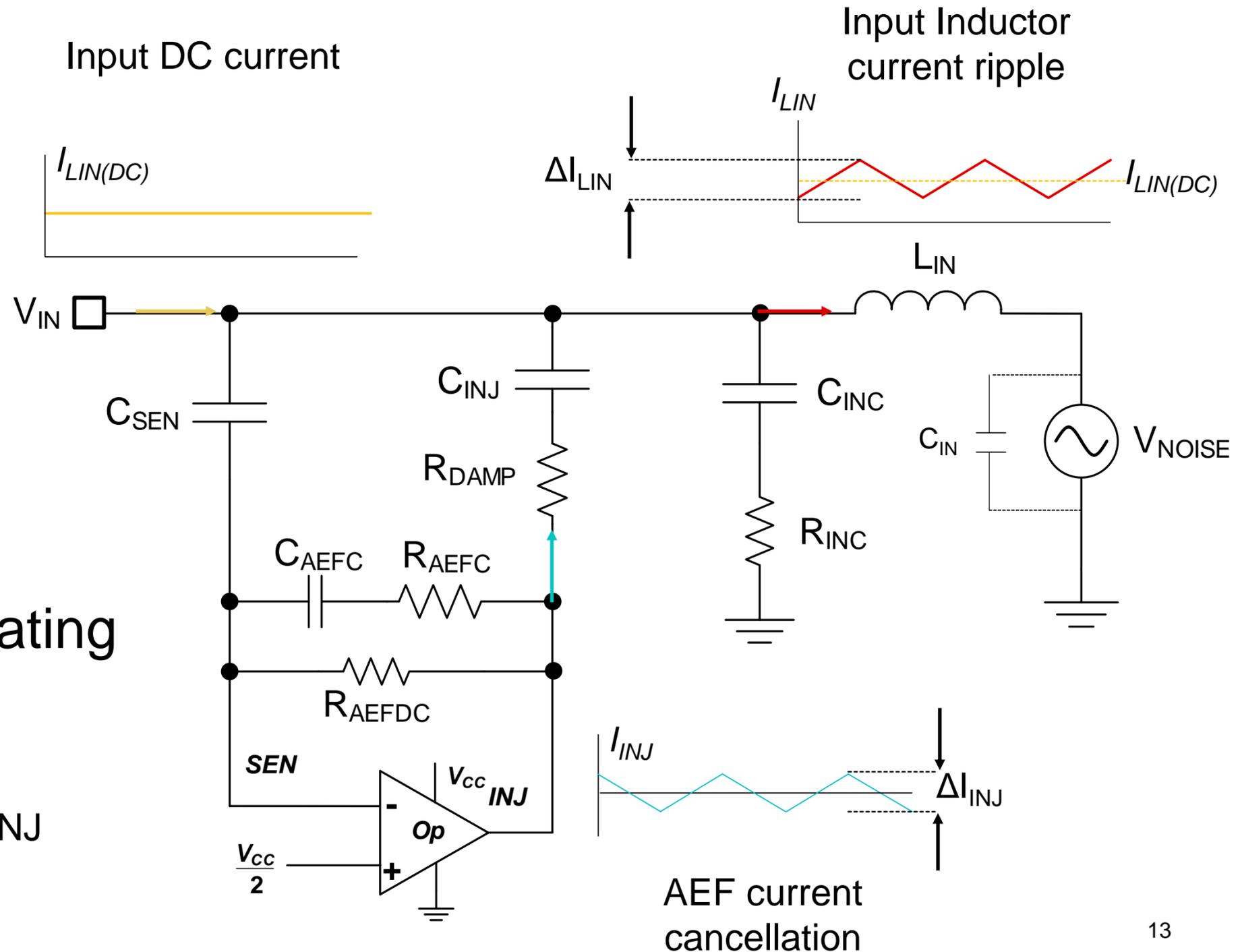
$C_{INJ}$  = AEF injection capacitor

- With  $G_{Op} = 100$ , filter can reduce  $L_F$  and  $C_{INJ}$  one-tenth compared to passive!



# EMI filtering: Active EMI filter

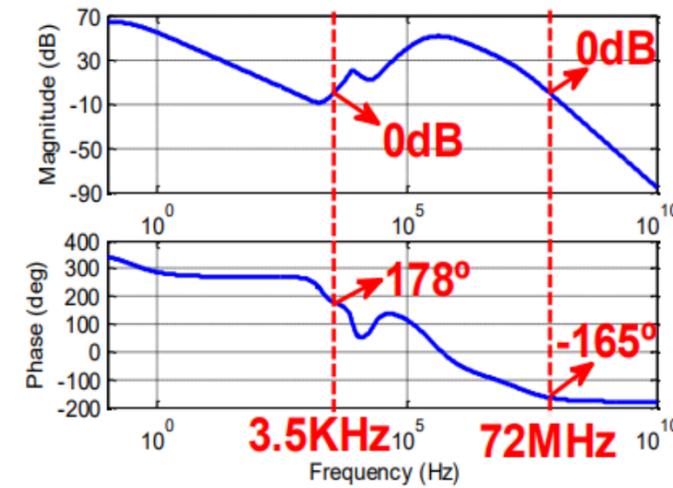
- Input voltage and current ripple cause EMI. Lowest ripple will result in lowest EMI
- Capacitive sensing and injection
  - No DC current into AEF
- AEF ripple current cancels ripple current of input inductor
- AEF is NOT limited to DC power rating
  - Limited to  $\Delta I_{INJ}$  canceling  $\Delta I_{LIN}$
- $L_{IN}$  or  $C_{IN}$  can be sized to meet  $\Delta I_{INJ}$  requirement



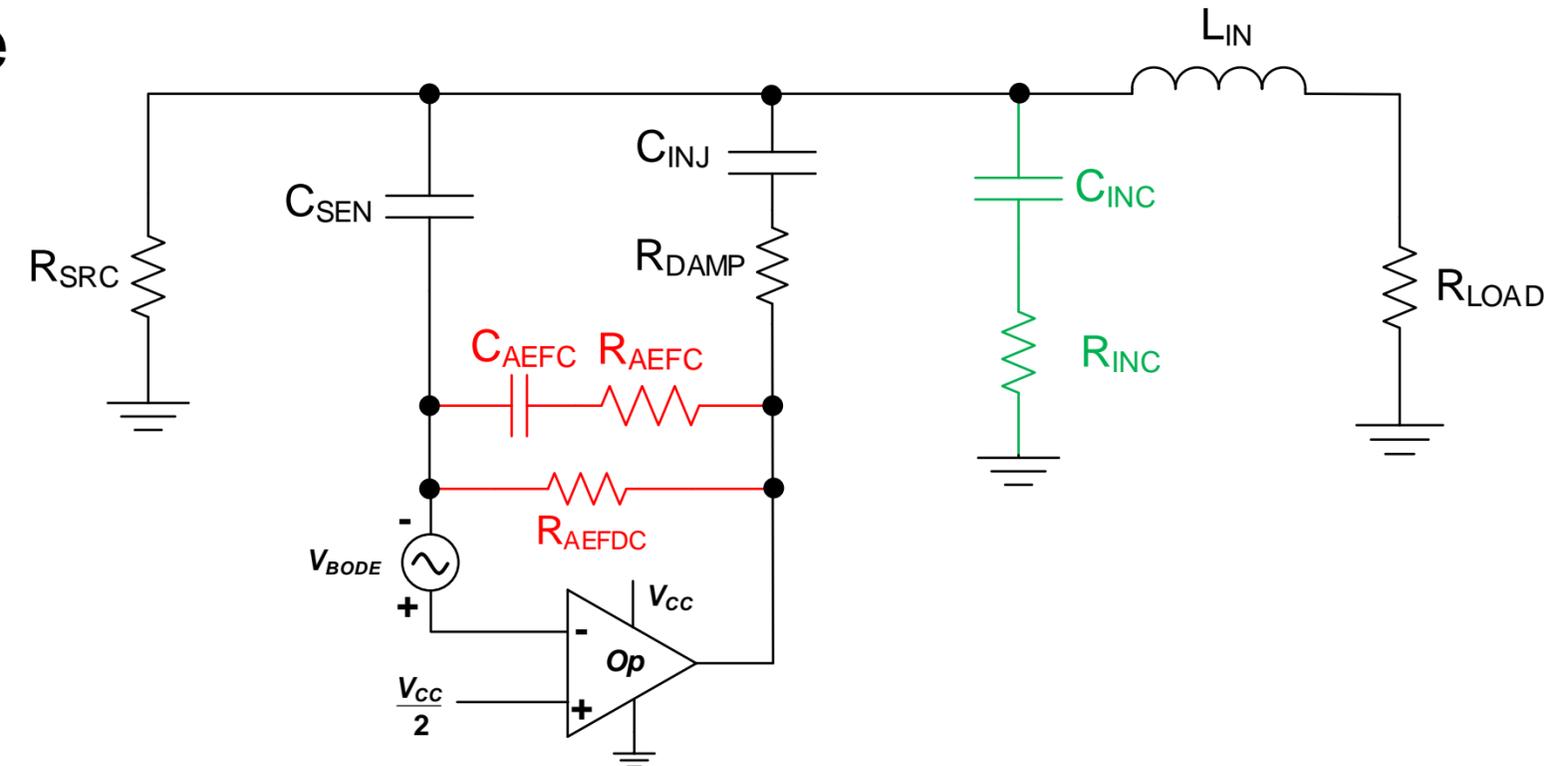
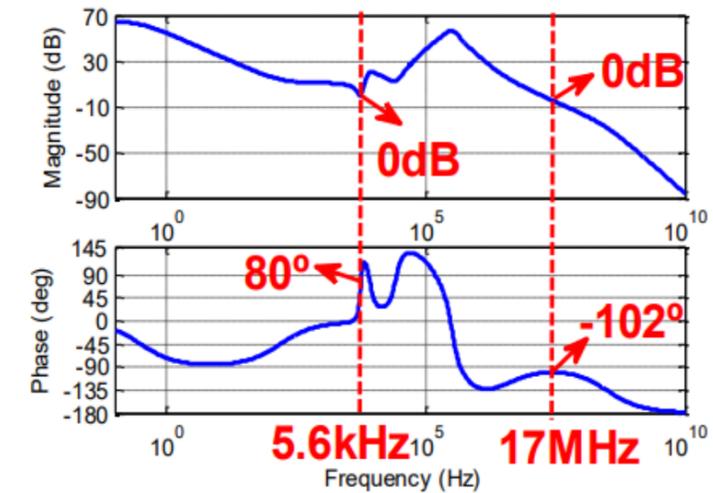
# EMI filtering: Active EMI filter Compensations

- Loop has two crossovers to compensate
- Two compensations:
  - Feedback compensation (AEFC)
  - Input compensation (INC)
- $R_{AEFDC}$  and  $C_{AEFC}$  set LF crossover
  - Gain could cross 0 dB close to 180° of phase
- $R_{INC}$  and  $C_{INC}$  set HF-crossover
  - Provides phase boost at high-frequency
  - $C_{INJ}$  parasitics limit SRF ~20 MHz

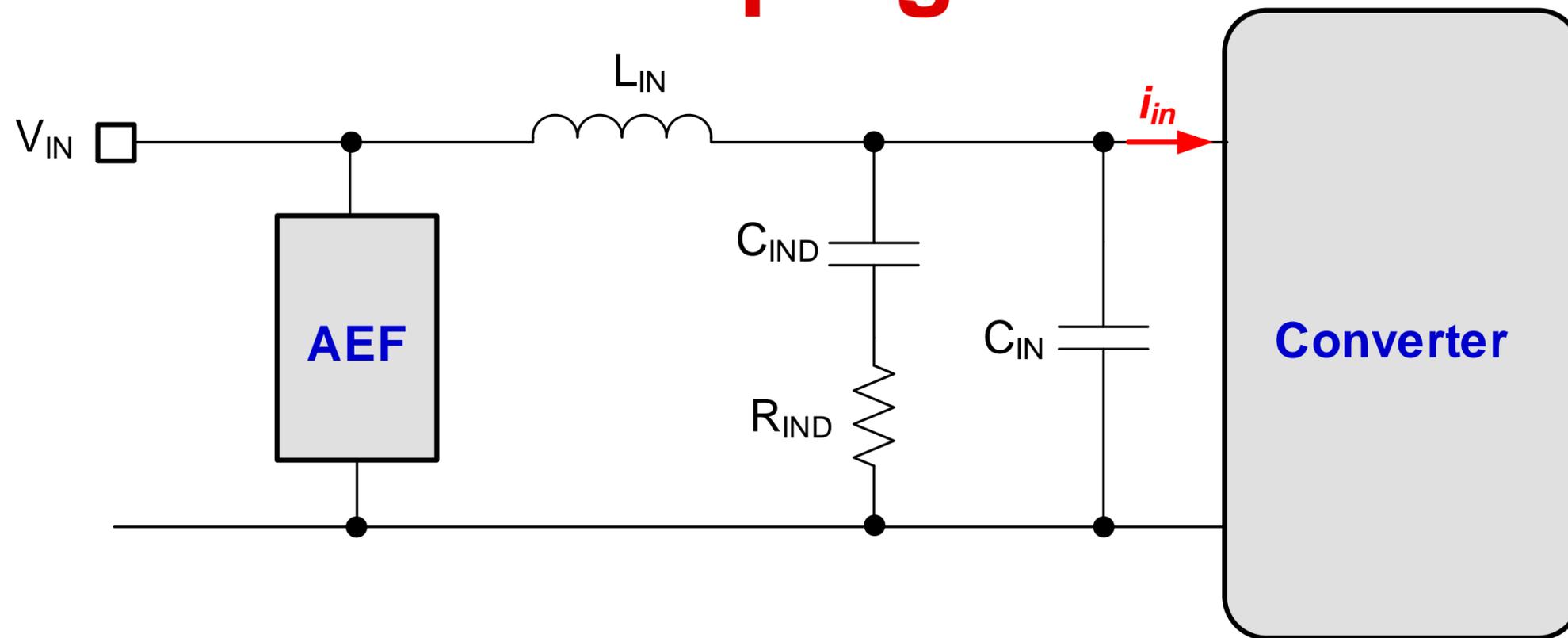
No compensation



Both LF & HF compensation



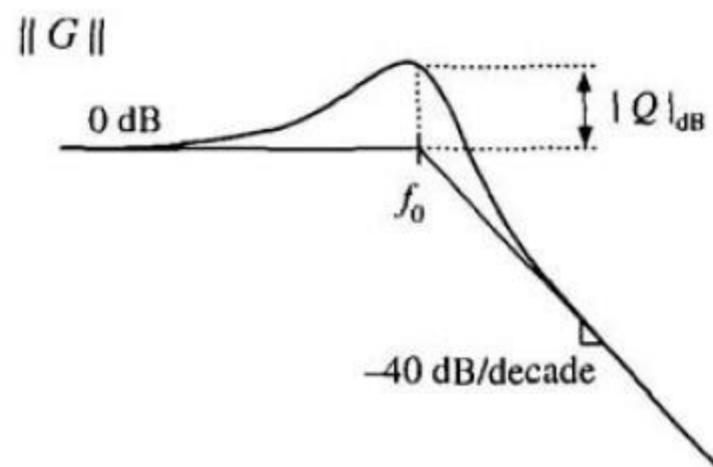
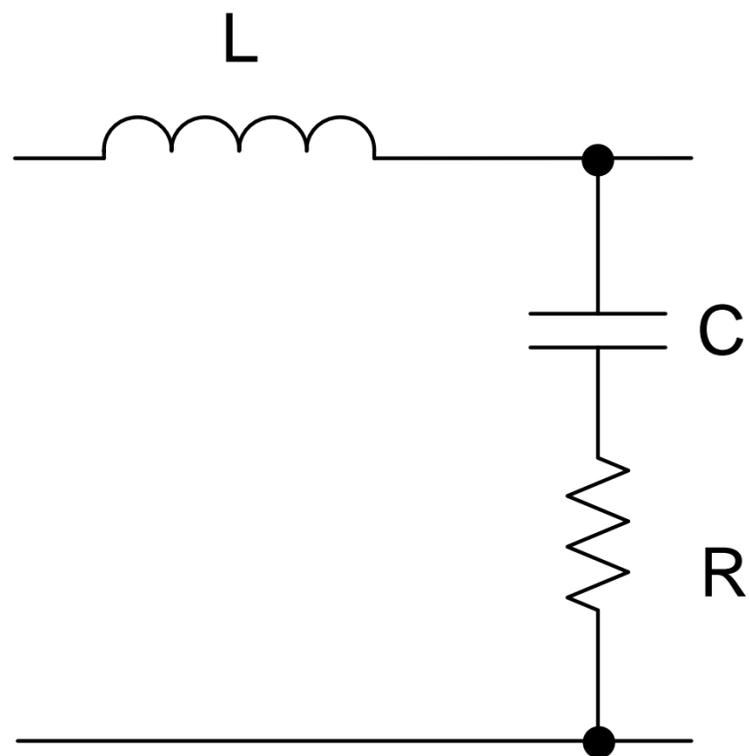
# Why do we need damping?



- Jitter, transients, or any other perturbation can cause an undamped response on an L-C filter.
- $C_{IN}$  and  $L_{IN}$  can resonate from regulator perturbations. A damping capacitor,  $C_{IND}$ , with ESR or resistor  $R_{IND}$ , is in parallel with  $C_{IN}$  for damping.
- AEF can be purely capacitive and resonate with  $L_{IN}$  if undamped. This may cause saturation and increased power loss.

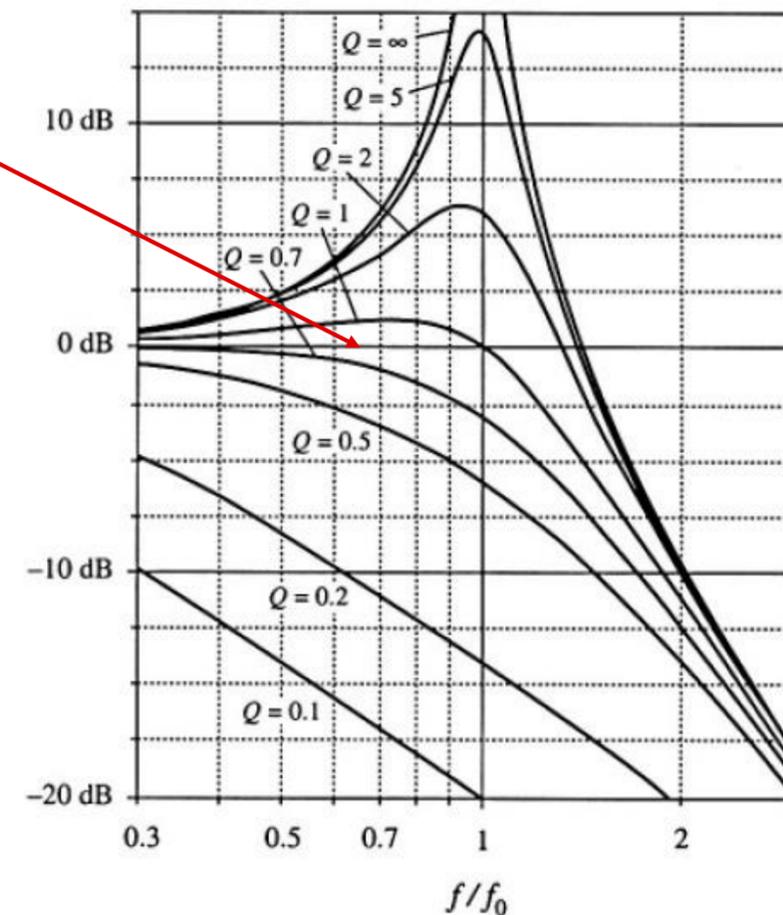
# Damping basics

For the filter to be damped against resonance, we need a Q between 0.7 to 1.0.

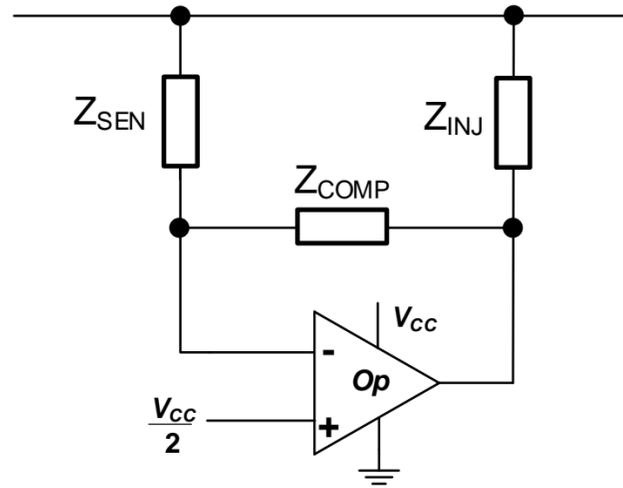


$$Q = \frac{1}{R} \sqrt{\frac{L}{C}}$$

**Quality factor**



# AEF undamped response



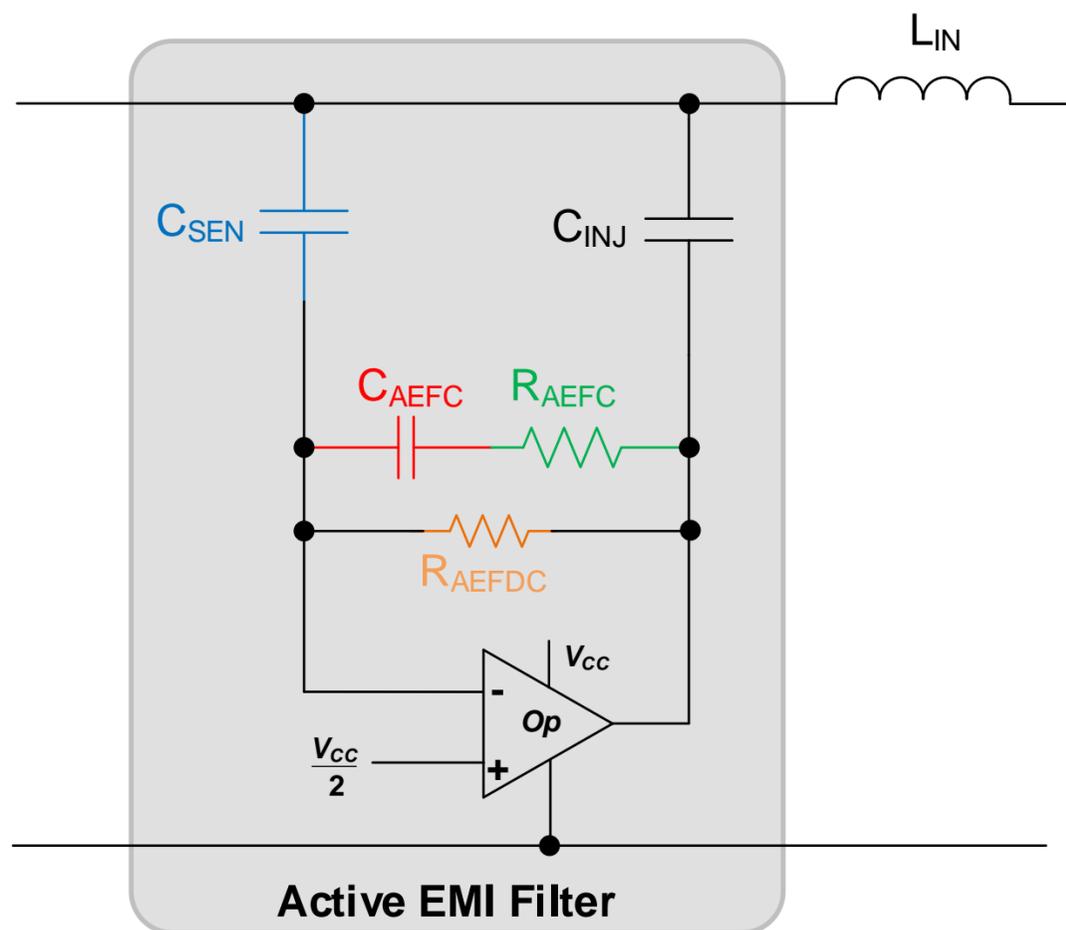
$$G_{Op} = \frac{Z_{COMP}}{Z_{SEN}}$$

$$G_{Op} = \frac{(Z_{CAEFC} + Z_{RAEFC}) \parallel Z_{RDC}}{Z_{CSEN}}$$

$$\approx \frac{Z_{CAEFC} + Z_{RAEFC}}{Z_{CSEN}} \approx \frac{Z_{CAEFC}}{Z_{CSEN}} \approx \frac{C_{SEN}}{C_{AEFC}}$$

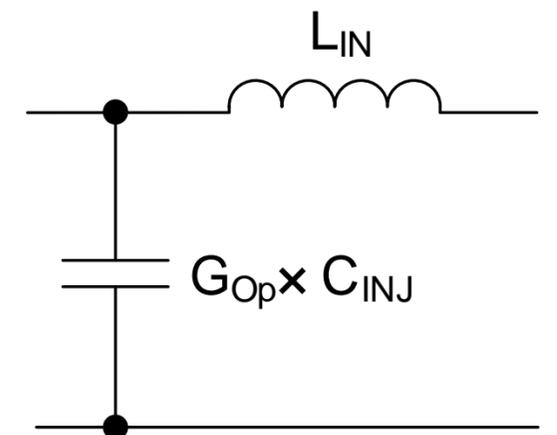
$$R_{DC} \gg Z_{AEFC}$$

$$Z_{CAEFC} \gg Z_{RAEFC}$$



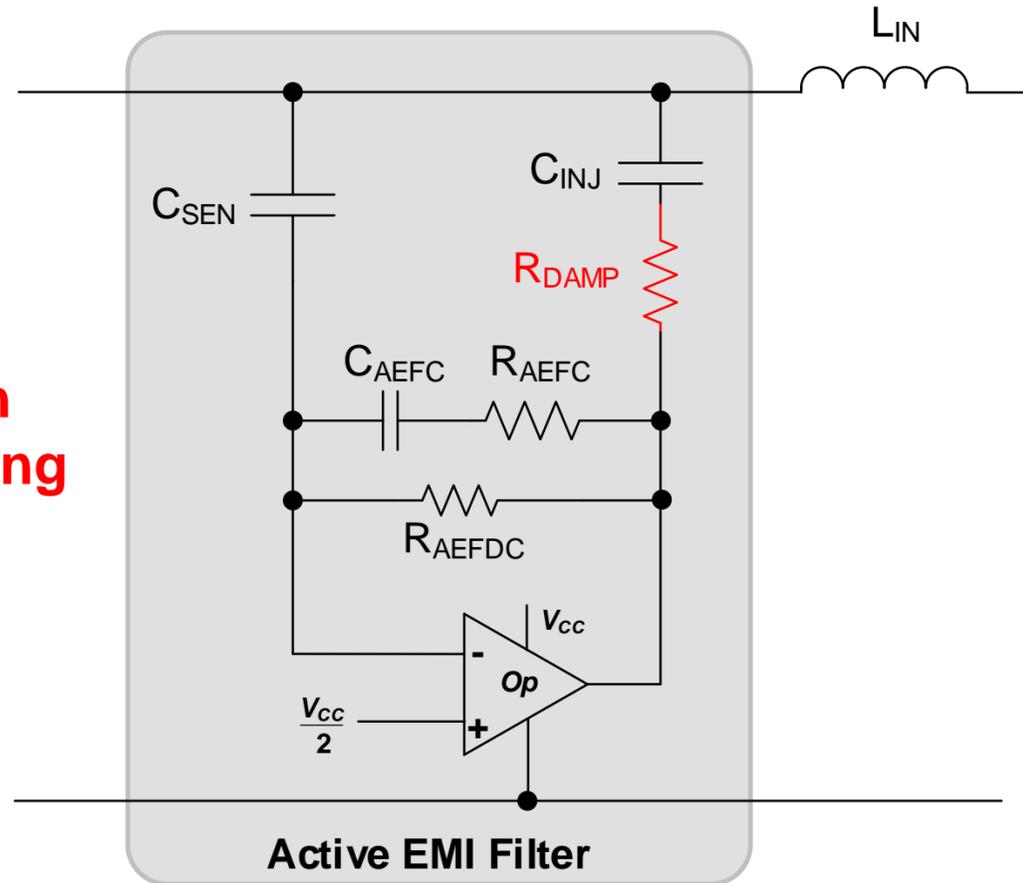
$$Z_{EQ} = \frac{Z_{CINJ}}{G_{Op}} = \frac{1}{sC_{INJ}G_{Op}}$$

(equivalent to a  $G_{Op} \times C_{INJ}$  capacitor)



# Damping method 1 (series damping)

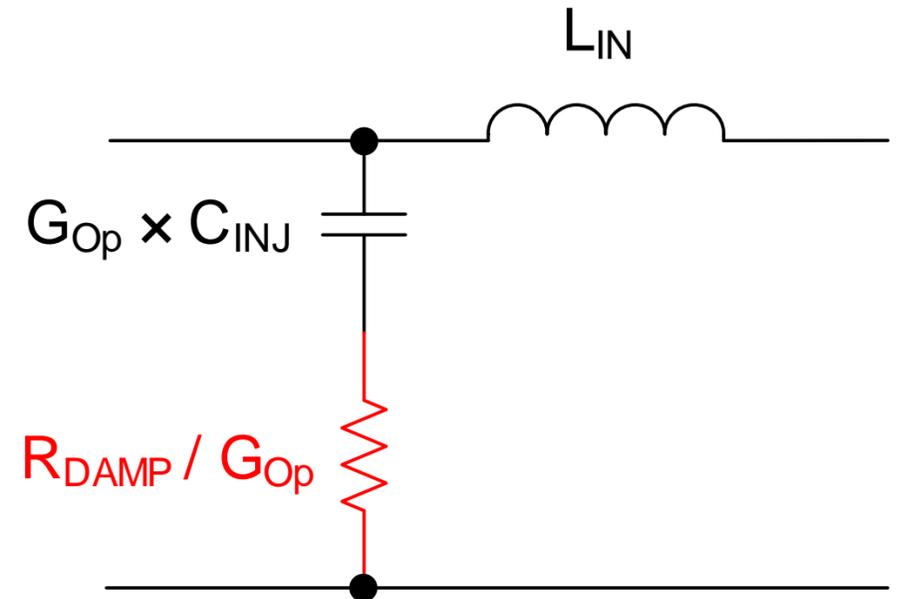
With damping



Equivalent impedance **with series damping:**

$$Z_{EqDamped} = \frac{Z_{RDAMP} + Z_{CINJ}}{G_{Op}}$$

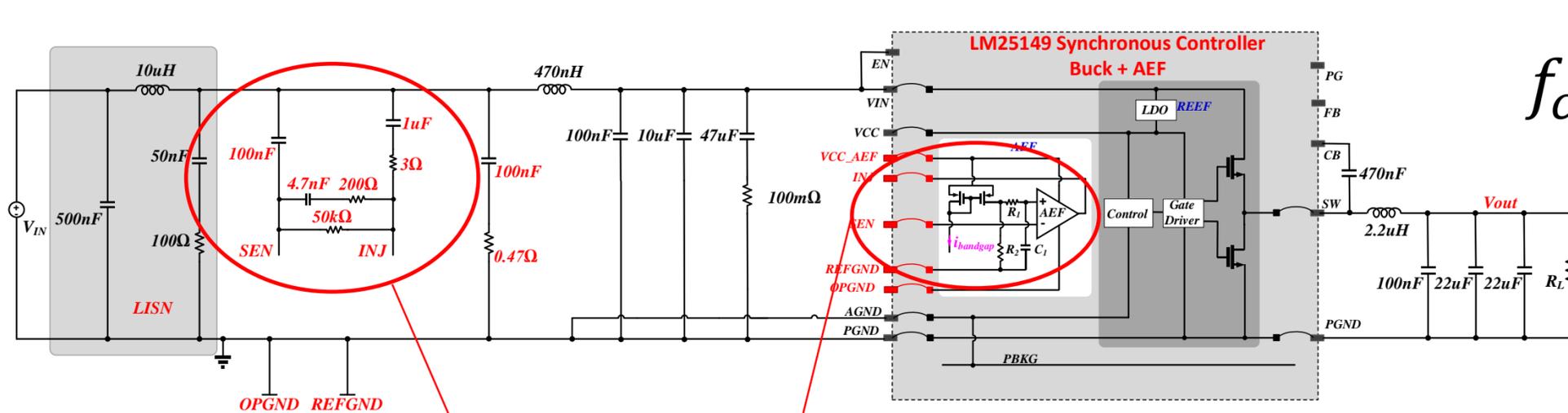
$$= \frac{R_{DAMP}}{G_{Op}} + \frac{1}{sC_{INJ}G_{Op}}$$



Low-frequency equivalent circuit with damping

$$Q = \frac{1}{R} \sqrt{\frac{L}{C}} = 1, R = \sqrt{\frac{L}{C}} \Rightarrow \frac{R_{DAMP}}{G_{Op}} = \sqrt{\frac{L_{IN}}{C_{INJ} \cdot G_{Op}}} \Rightarrow R_{DAMP} = \sqrt{\frac{L_{IN} \cdot G_{Op}}{C_{INJ}}}$$

# Damping method 1 example, $f_{sw} = 2 \text{ MHz}$

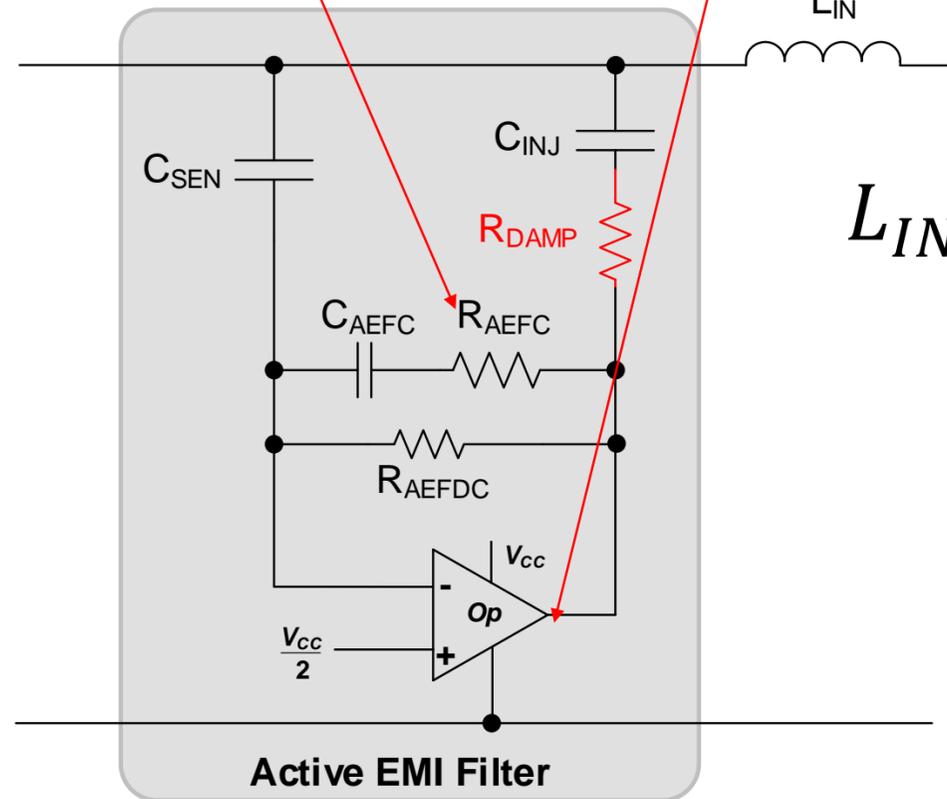


$$f_c = \frac{f_{sw}}{10^{|Att|/40}} = \frac{2 \text{ MHz}}{10^{|60|/40}} = 63 \text{ kHz}$$

$$G_{op} \approx \frac{C_{SEN}}{C_{AEFC}} = \frac{100 \text{ nF}}{4.7 \text{ nF}} = 21$$

Compensation and damping

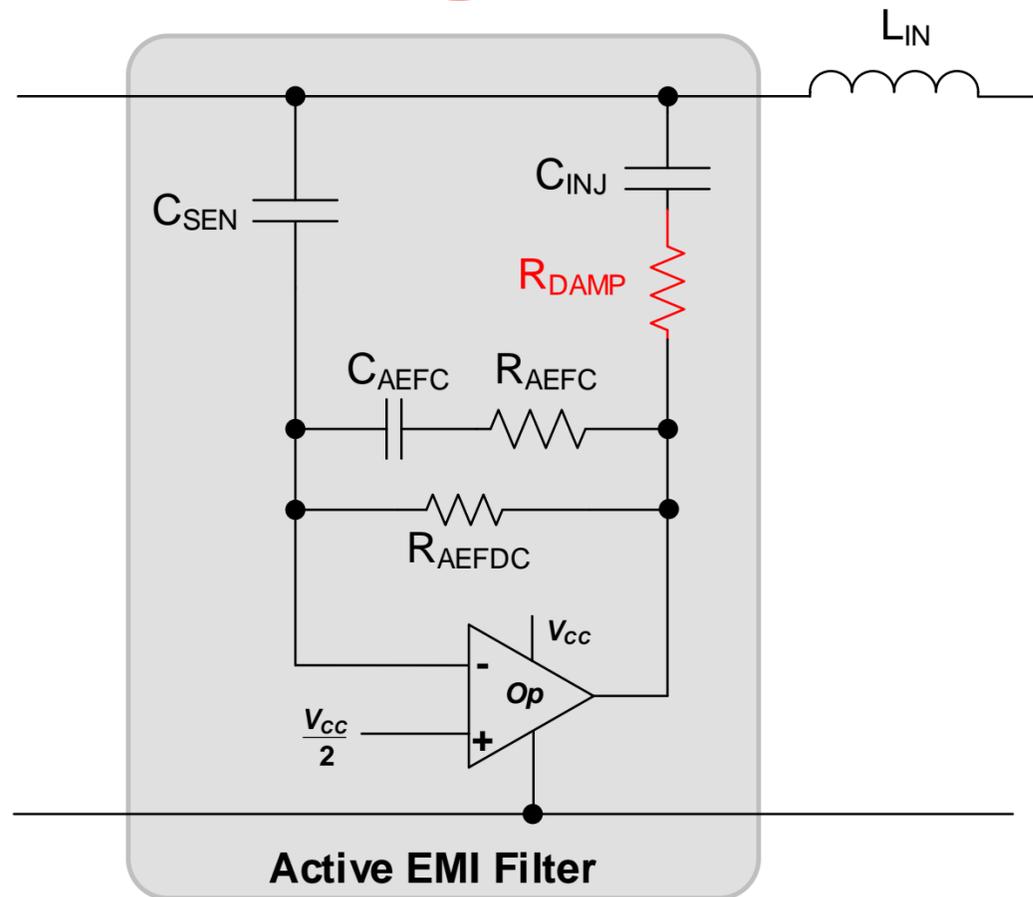
AEF amplifier



$$L_{IN} C_{INJ} = \frac{1}{G_{op} (2\pi f_c)^2} = \frac{1}{21 (2\pi * 63 \text{ kHz})^2} = 304 \text{ [nH} \cdot \mu\text{F]}$$

$$R_{DAMP} = \sqrt{\frac{G_{op} \cdot L_{IN}}{C_{INJ}}} = \sqrt{\frac{21 \cdot 470 \text{ nH}}{1 \mu\text{F}}} = 3.1 \Omega$$

# Series damping summary



$$f_c = \frac{f_{sw}}{10^{|Att|/40}}$$

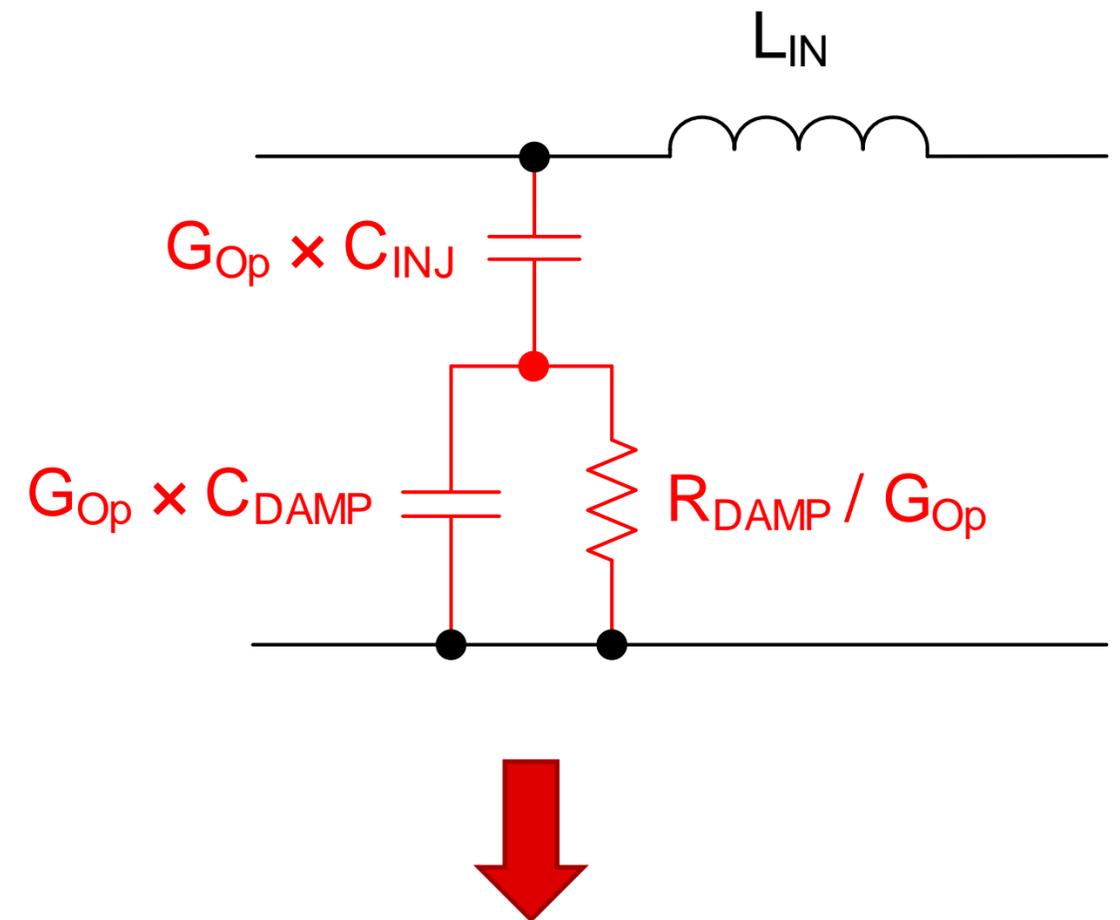
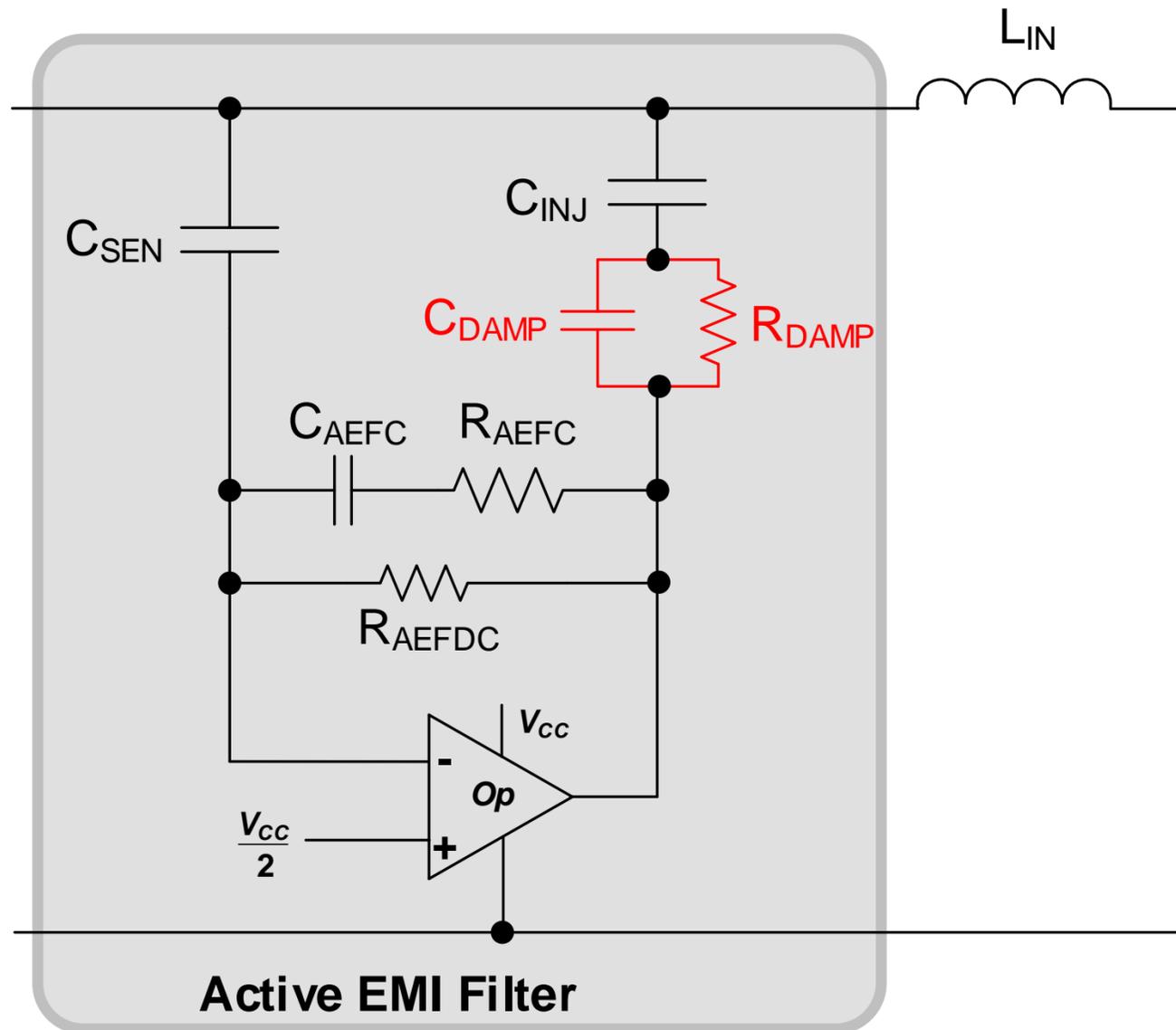
$$G_{Op} \approx \frac{C_{SEN}}{C_{AEFC}}$$

$$L_{IN} C_{INJ} = \frac{1}{G_{Op} (2\pi f_c)^2}$$

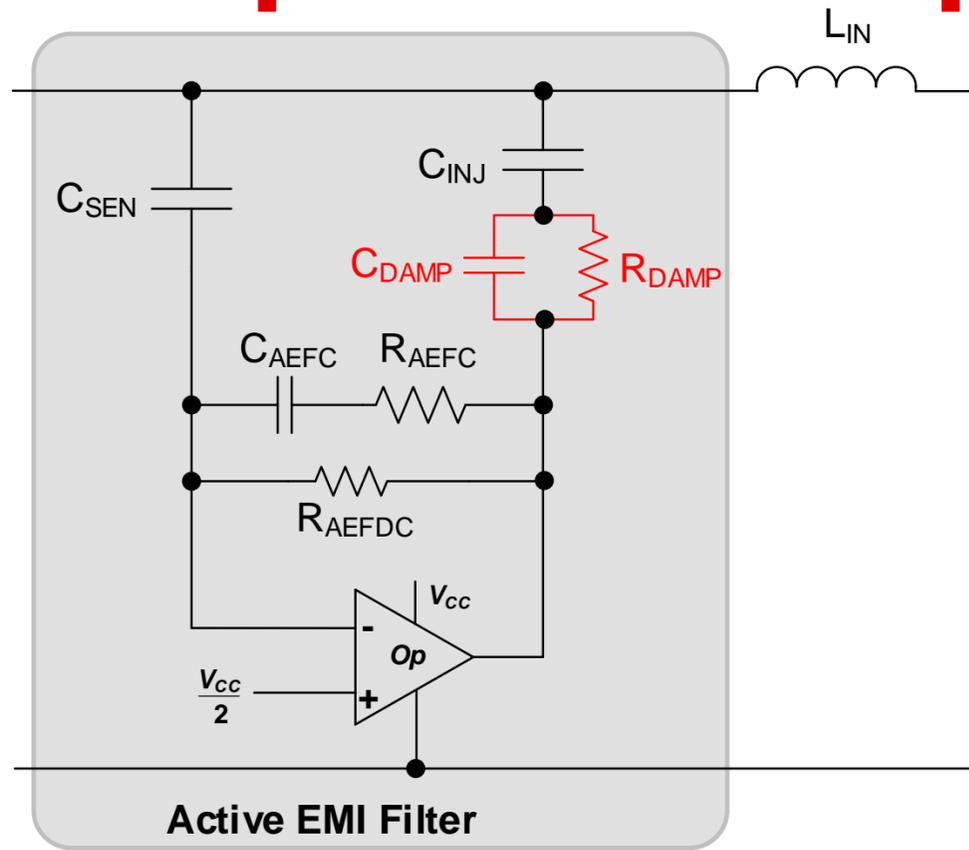
- Damping method 1 is simple
- $G_{Op}$  acts like a capacitive multiplier
- This method can be applied for  $\sim 2\text{MHz } f_{sw}$
- Other damping methods can be used for lower switching frequency

$$R_{DAMP} = \sqrt{\frac{G_{Op} \times L_{IN}}{C_{INJ}}}$$

# Damping method 2 – parallel capacitor (440 kHz)

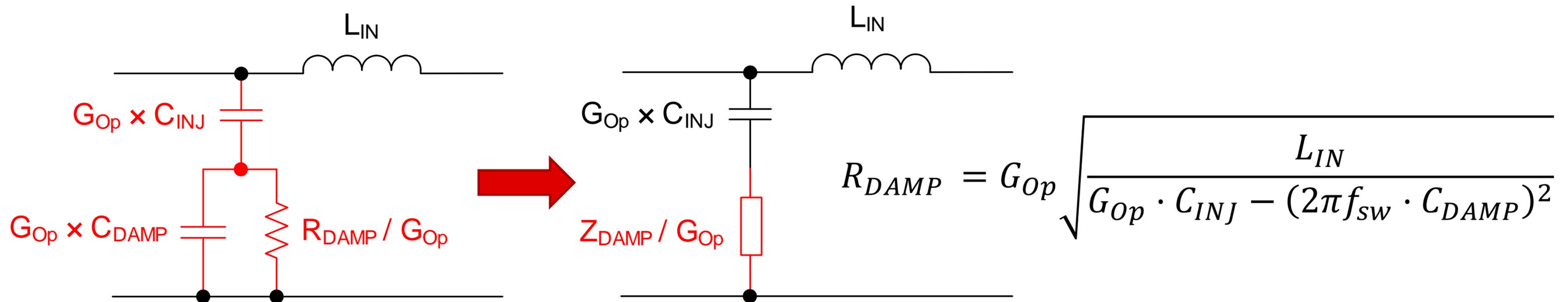


# AEF optimal damping for a third-order system



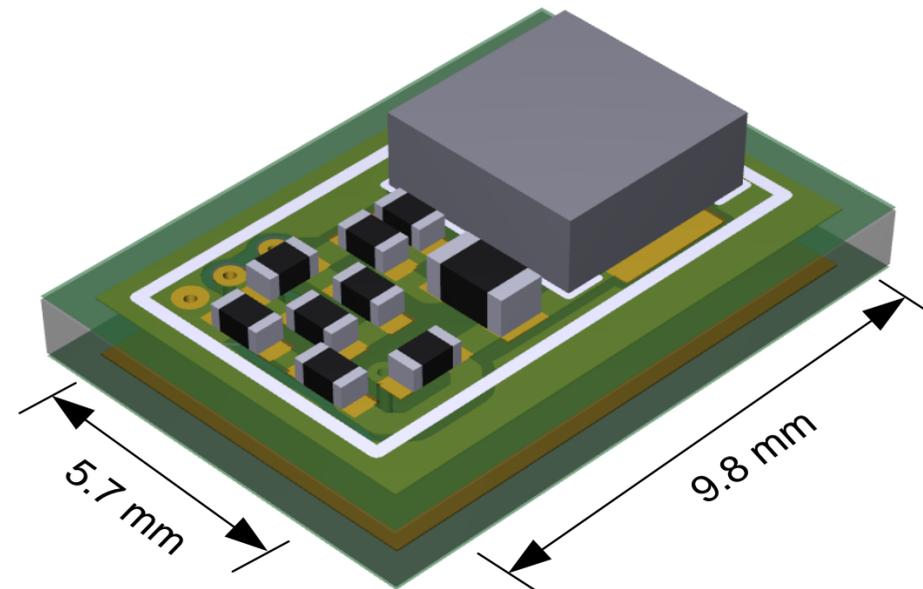
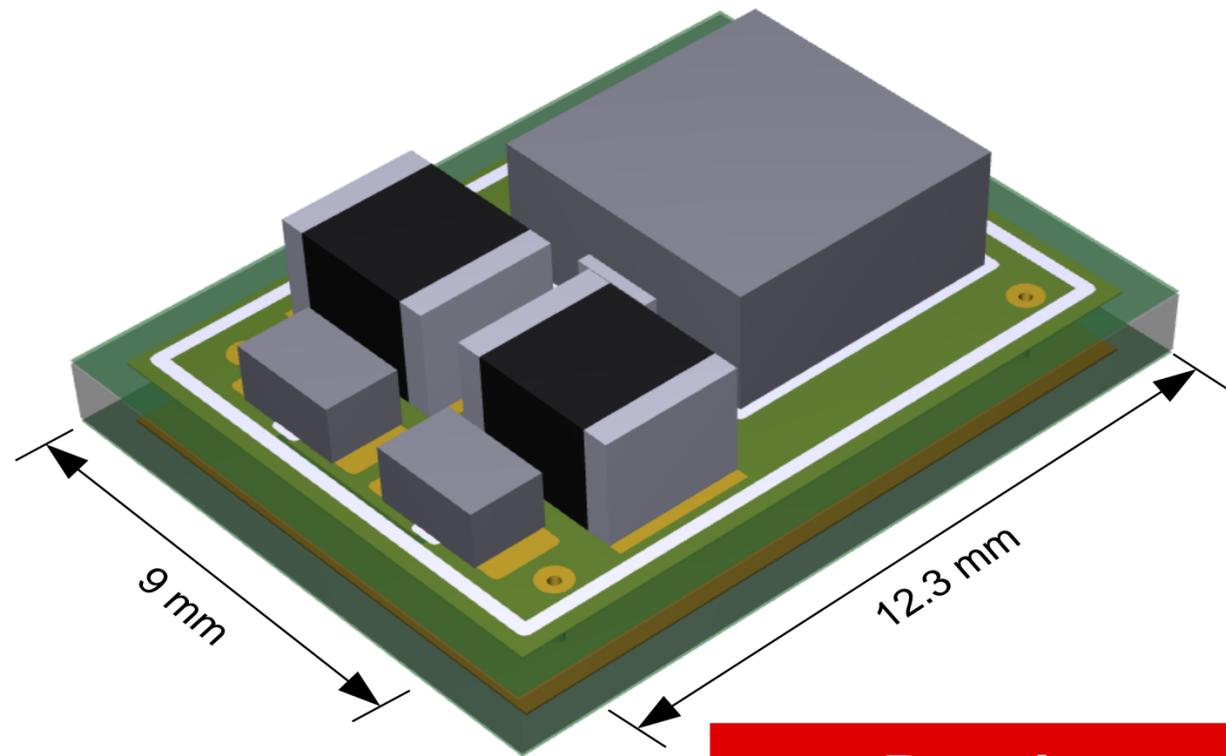
$$Z_{DAMP} = \frac{1}{\sqrt{\left(\frac{1}{R_{DAMP}}\right)^2 + (2\pi f_{sw} \cdot C_{DAMP})^2}}$$

$$Z_{DAMP} = \sqrt{\frac{L_{IN}}{G_{Op} \cdot C_{INJ}}}$$



# Passive vs active filter optimized layouts

- Traditional passive layout (left) uses a taller inductor and larger capacitors.
- Active EMI filter (right) uses smaller and cheaper components with improved filter performance.



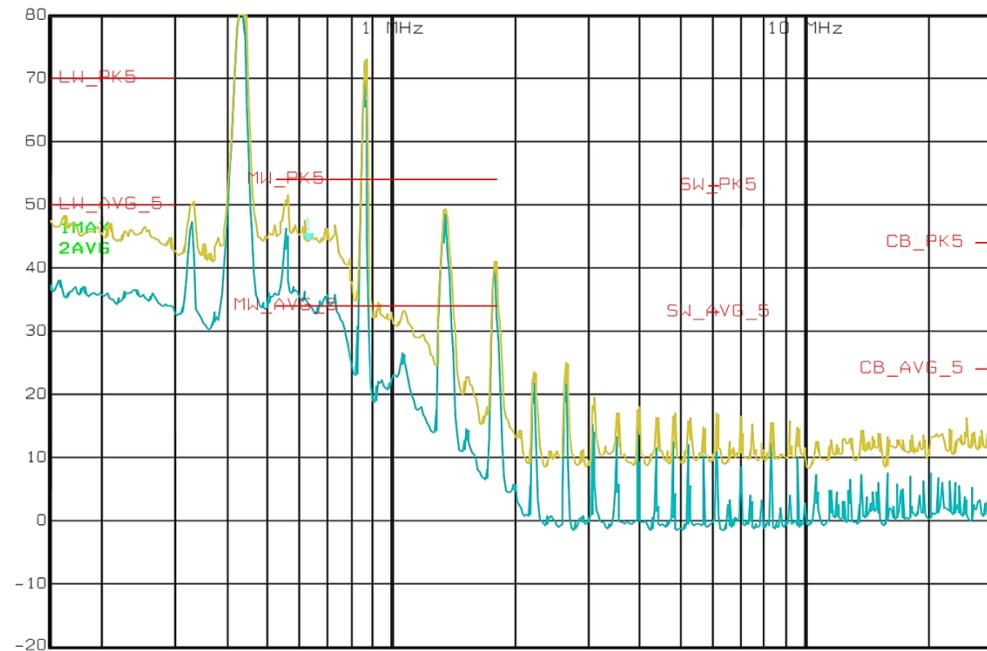
Passive	Active
110 mm <sup>2</sup>	56 mm <sup>2</sup>
\$2.71*	\$1.70*

\*as of April 2021

# Passive vs active CISPR 25 results comparison

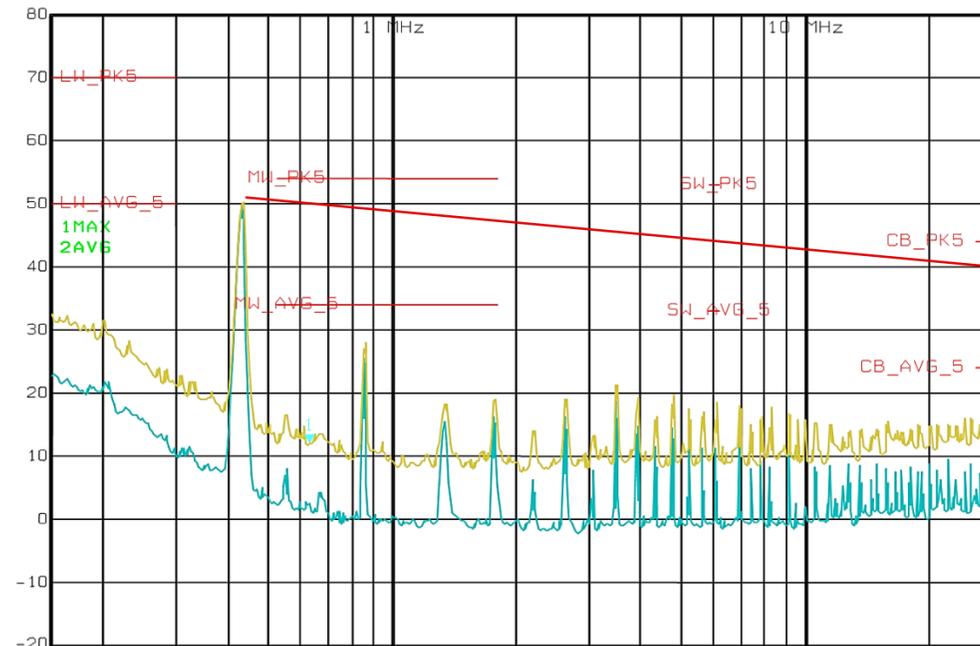
$V_{IN} = 13.5\text{ V}$ ,  $V_{OUT} = 5\text{ V}$ ,  $I_{OUT} = 5\text{ A}$ ,  $F_{SW} = 440\text{ kHz}$

## No EMI filter



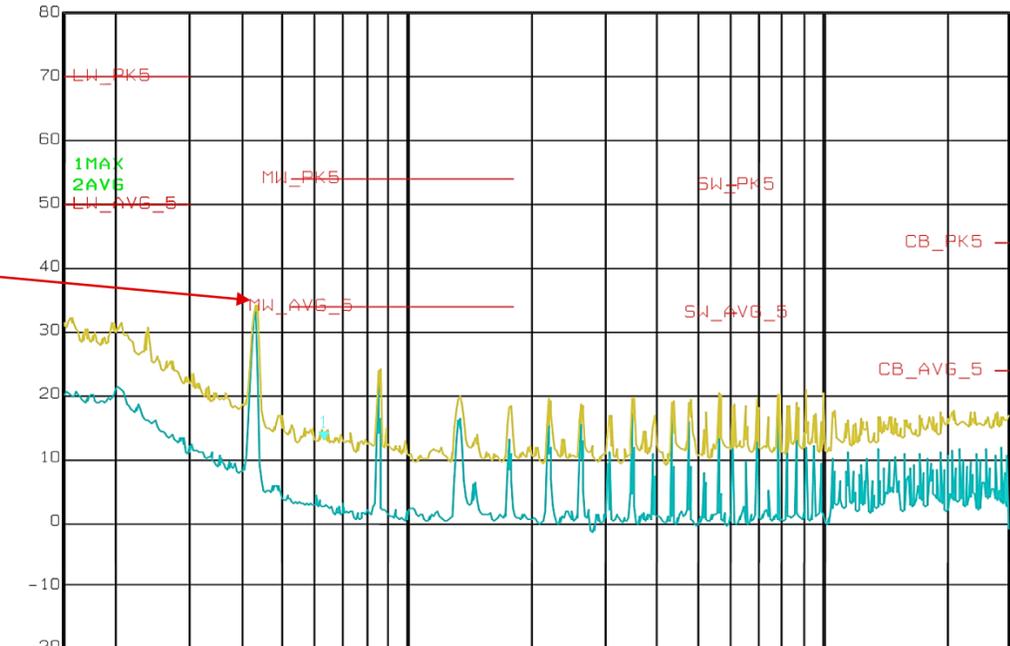
## Passive EMI filter

$L_{IN} = 2.2\ \mu\text{H}$ ,  $C_F = 2 \times 10\ \mu\text{F}$



## Active EMI filter

$L_{IN} = 1\ \mu\text{H}$ ,  $C_{INJ} = 0.47\ \mu\text{F}$

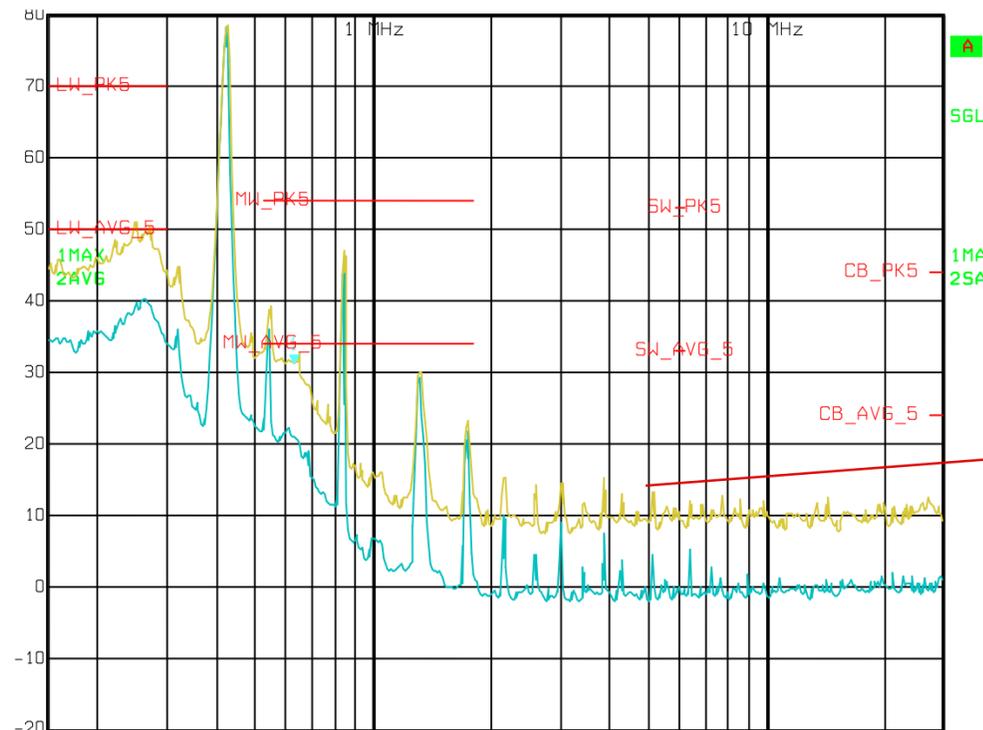


Start: 150 kHz **CISPR 25 Class 5 peak** Stop: 30 MHz  
**CISPR 25 Class 5 average**

# EMI filtering: Active EMI filter components

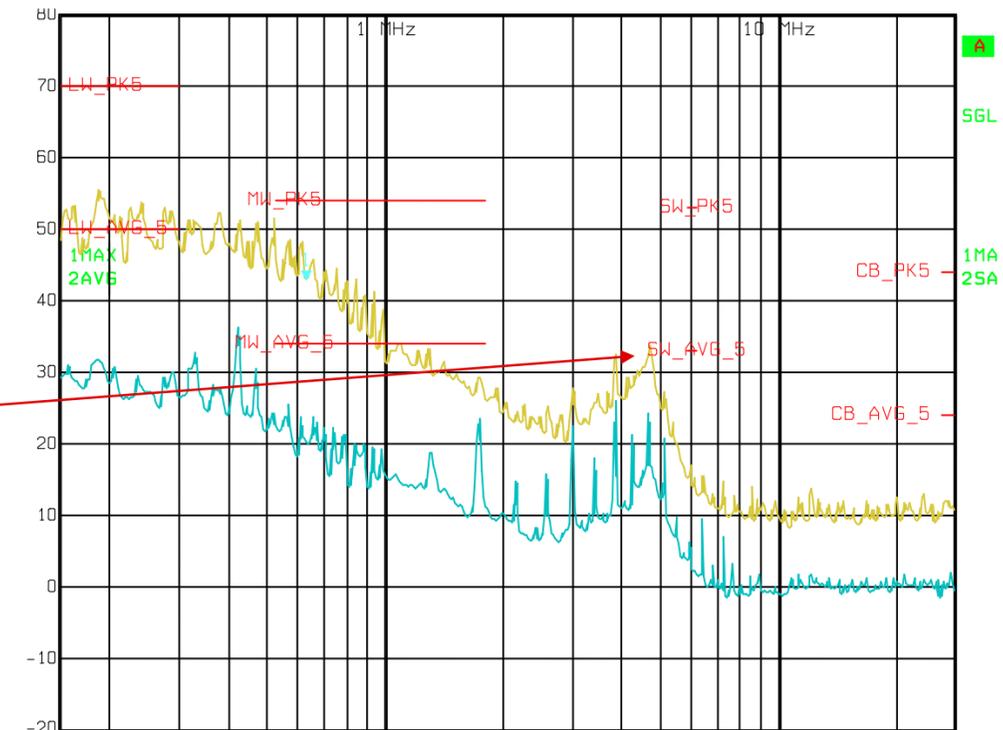
- Poorly selected AEF components can negatively impact EMI:
  - $C_{INJ}$  with SRF **5 MHz** caused resonance (*less than system loop crossover of 20 MHz*).
    - Use a HF crossover **lower** than the SRF of active EMI components

## AEF disabled



Start: 150 kHz      CISPR 25 Class 5 peak      Stop: 30 MHz  
                         CISPR 25 Class 5 average

## AEF enabled with poor components



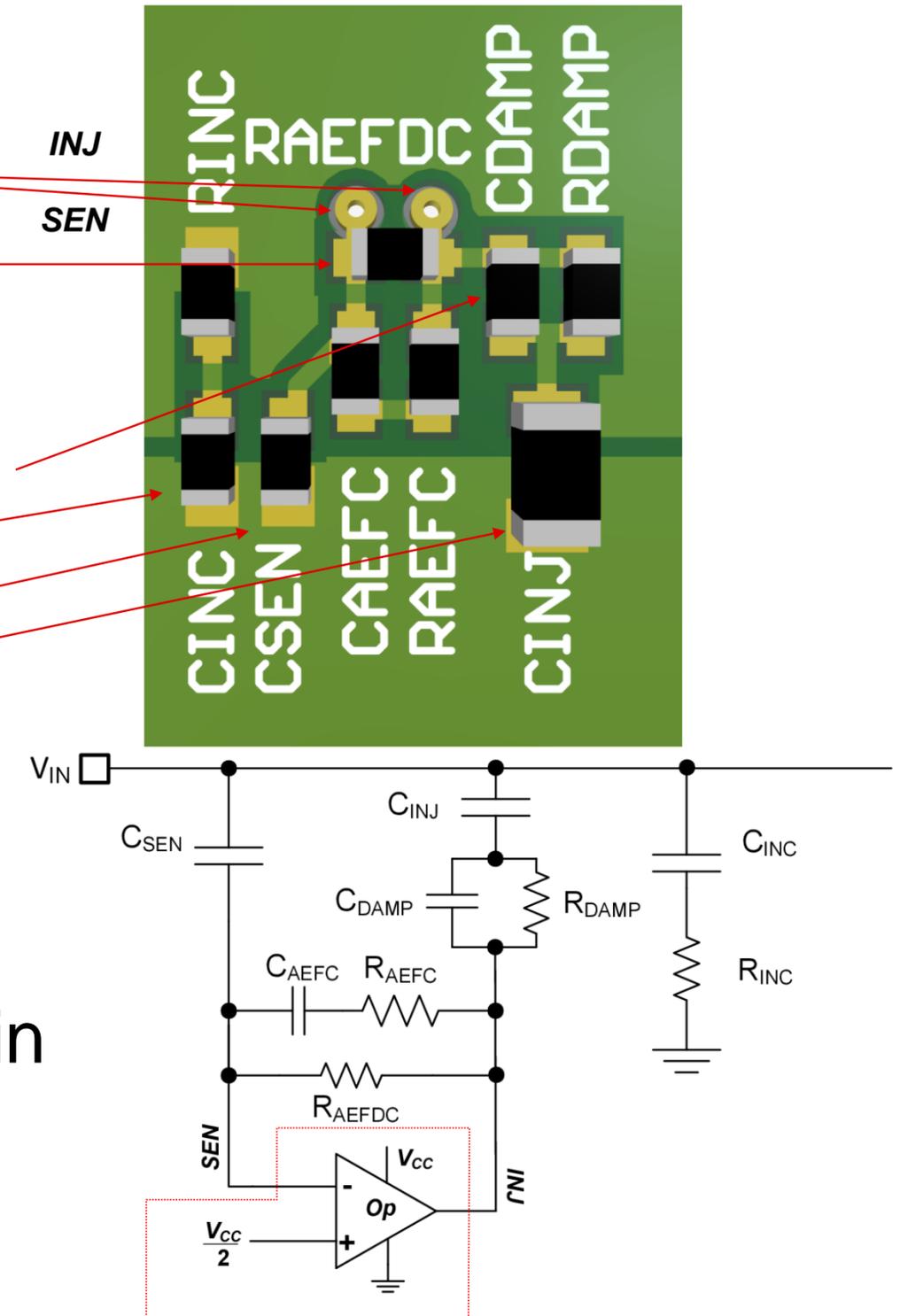
Start: 150 kHz      CISPR 25 Class 5 peak      Stop: 30 MHz  
                         CISPR 25 Class 5 average

# EMI filtering: AEF layout and other considerations

- Route SEN and INJ traces differentially
- Place  $R_{AEFDC}$  at SEN and INJ vias
  - Place  $C_{AEFC}$  and  $R_{AEFC}$  to form tight loop
- $C_{DAMP}$  &  $R_{DAMP}$  close to AEF compensation (AEFC)
- $R_{INC}$  and  $C_{INC}$  away from noisy ground
- $C_{SEN}$  close to AEF compensation
- $C_{INJ}$  close to damping

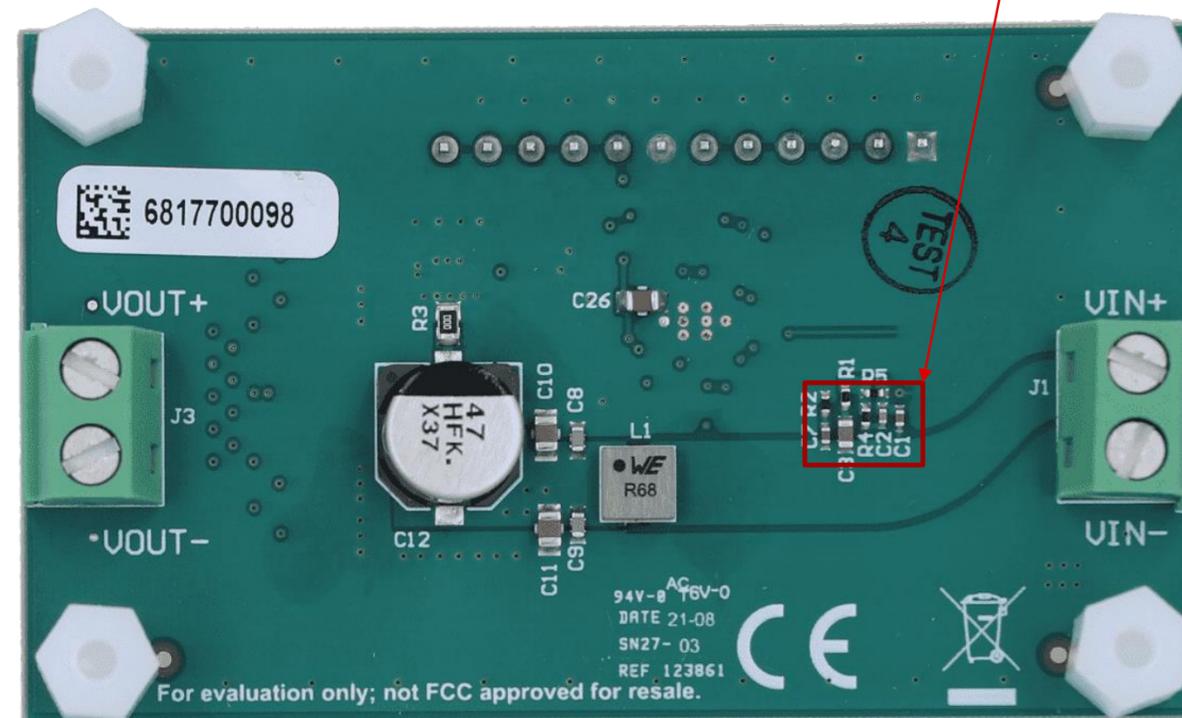
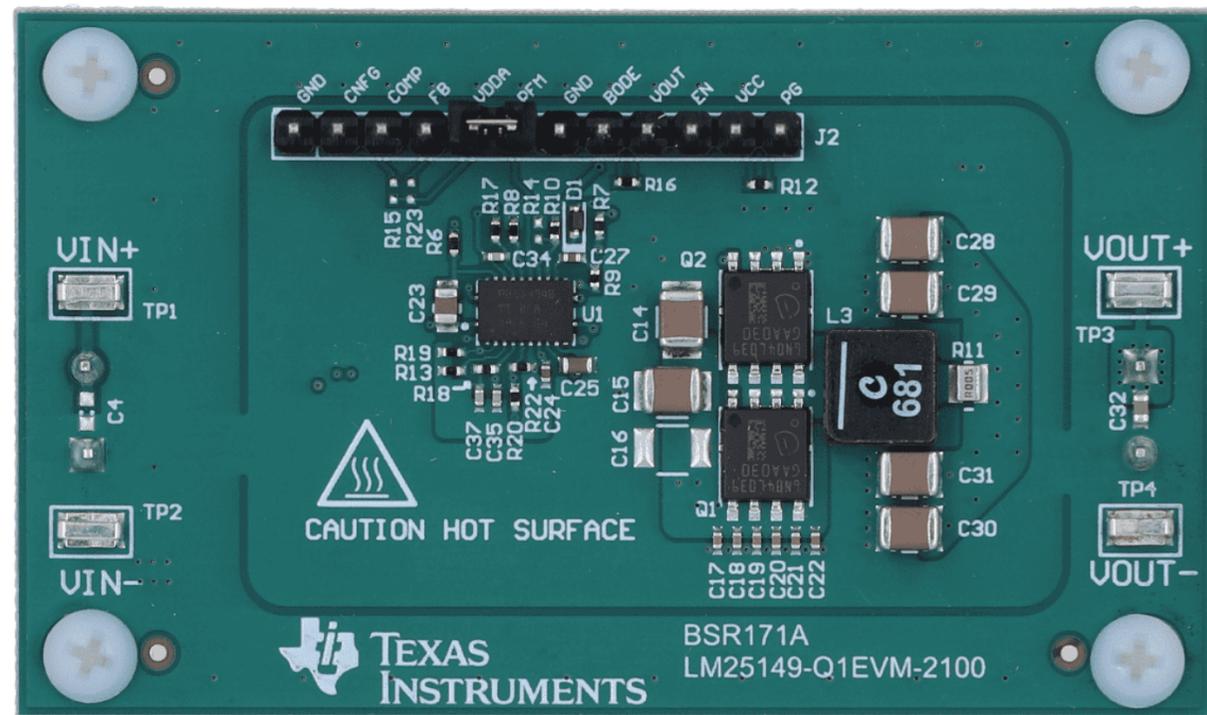
*At the Op-amp / IC:*

- AEF amplifier VCC decoupling capacitor close to pin
- AEF amplifier AVSS grounded on quiet ground



# LM25149-Q1EVM-2100 Buck controller with AEF

- LM25149-Q1EVM-2100 evaluation board uses LM25149-Q1 synchronous buck controller with integrated AEF.



# Summary

- EMI can cause unwanted interference between electronics
- EMI filters are typically used to mitigate EMI
- EMI filters take cost and size, and come with limitations
- Active EMI filter uses an op-amp as an active capacitor
- AEF compensation
- AEF damping
- Results
- Layout guidelines



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